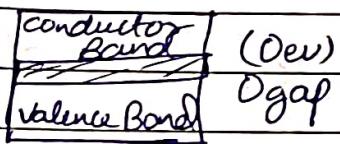


CL WADHWA
BL THAREJA
(EKeeda)
(Crat Academy plus)
(Neso Academy)

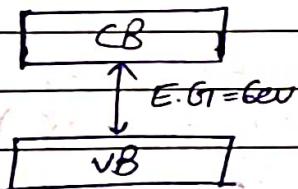
21/12/2020

FCECOO3(FEE)

Conductor



Insulator



Semi-conductor

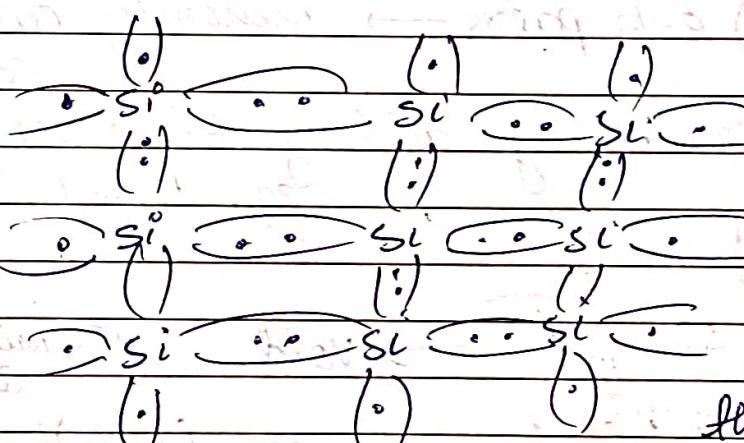


- At 0K, semiconductor behaves as insulator.
- At $T > 0K$, some e's move to the CB and thus it allows the flow of current.

Advantages of Si over Ge \rightarrow (High speed & Bandwidth)

- 1) Si^0 is less temp sensitive (temp stability)
- 2) Si^0 is less expensive & available in large amounts
- 3) less I_s (saturation current),
 $\rightarrow Si, Ge \rightarrow 4$ valence electrons

\rightarrow Intrinsic semiconductors: (Pure semiconductors)

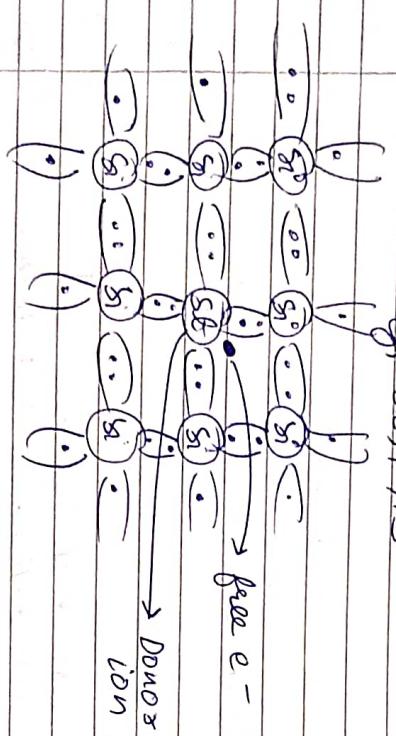


* $Si^0 Ge$ - As $T \uparrow$, resistivity \downarrow

→ Extrinsic semiconductor



- 1) n-type: created by adding pentavalent atoms
(Group 5) e.g.: Sb, P, As

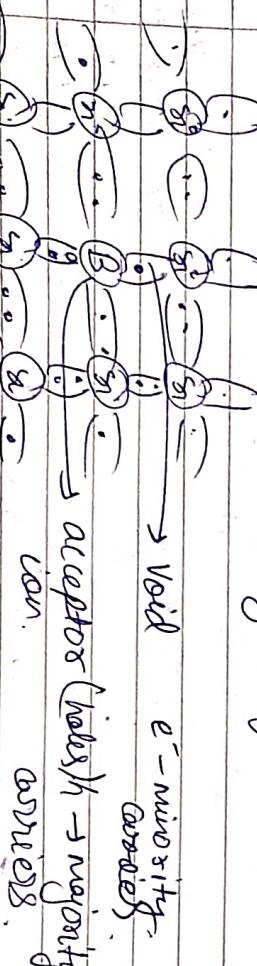


→ e⁻ due to donor atoms
→ e-h pairs due to thermal energy.

e's → majority carriers

(e-h pair) e-h pairs → minority carriers
(Group-B)

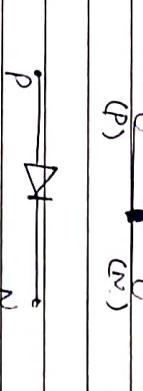
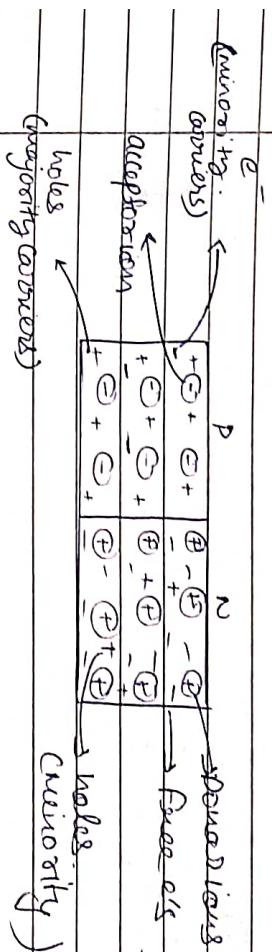
- 2) p-type: created by adding trivalent atoms
e.g., B, Ga, In



Semiconductor Diodes

22/12/2020

→ Diode : 1st solid state diodes



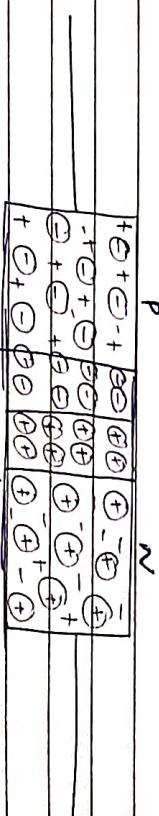
→ Diffusion of holes & e's takes place due to diff in concentration.

→ Carriers move from high conc to low conc.

holes → move from P to N

e's → move from N to P

→ Recombination will take place leaving behind $\textcircled{+}$ ions on n-side & $\textcircled{-}$ ions on p-side.



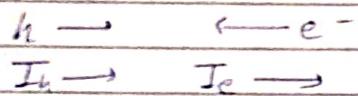
Depletion region / space charge region created.

Now hole would be repelled by ①
 Δe 's would be supplied by ②

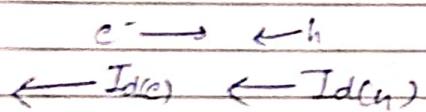
There will be a ϕ barrier potential set up
which results in an E that prevents further
movement of carriers takes place due to E .
(called drift current)

PN

Majority (diffusion current) (CM)

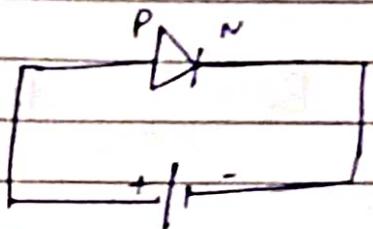


Minority (Drift current) (Thermal effect) (UA/nA/PA)

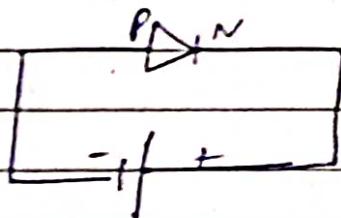


Forward & Reverse Bias

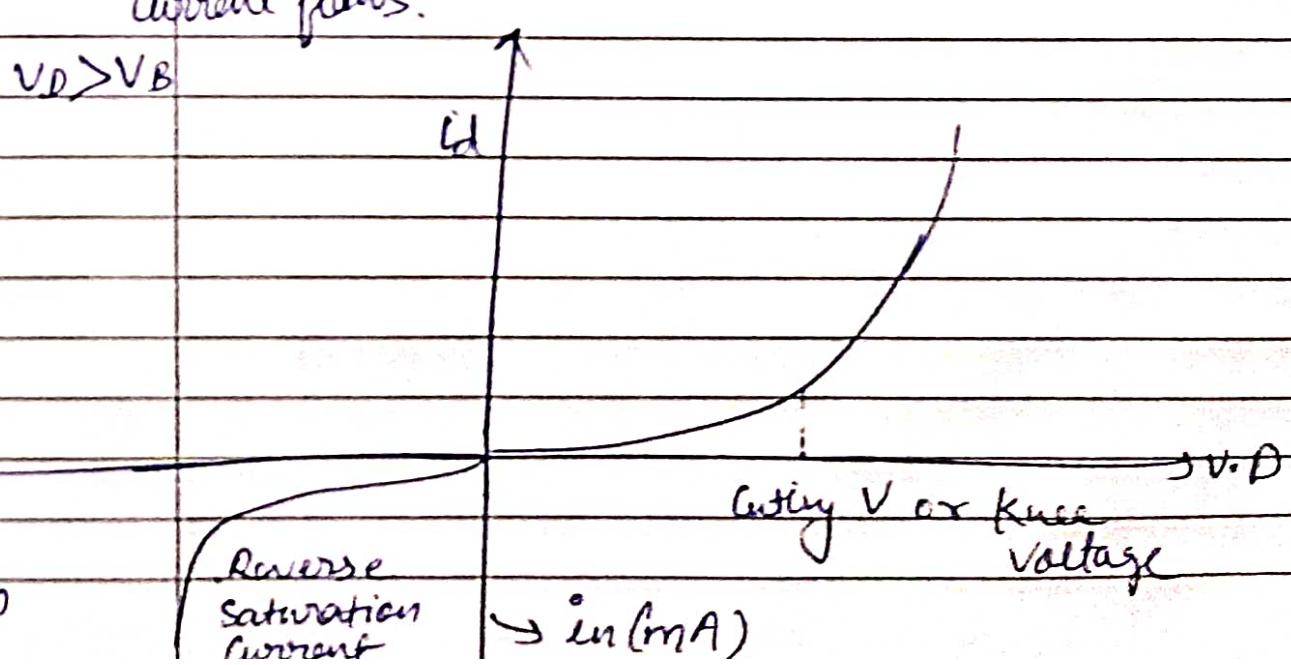
Forward Bias



Reverse bias.



- majority carriers are pushed towards junction
 - when they collide, recombination takes place
 - Depletion region becomes thinner.
 - (mA)
- Holes repelled by \rightarrow +ve plate
 e^- 's " " \rightarrow -ve plate
- $w \downarrow \rightarrow$ Barrier gets
Current flows.
- majority carriers are pushed away from the junction (no flow of I due to majority carriers)
 - The E Barrier strength is increased due to the external voltage
 - Depletion region widens.
 - Current flow would be due to minority carriers.
 - This current is very small, ($\text{in } \mu\text{A}/\text{nA}/\text{pA}$) called reverse saturation current.



$$I_d = I_s (e^{\eta \frac{V_d}{kT}} - 1)$$

I_s = Reverse saturation current

I_d = Diode current

V_t = Thermal voltage = kT (k = Boltzmann Const
 $= 1.38 \times 10^{-23} \text{ J/K}$)

$\hookrightarrow 26 \text{ mV at } R.T(27^\circ\text{C})$ ($e = 1.6 \times 10^{-19} \text{ C}$)
(25.8 mV).

$V_o \rightarrow$ applied voltage

η = physical contraction parameter

F.B

R.B

$$I_d = I_{\text{max}} - I_s$$

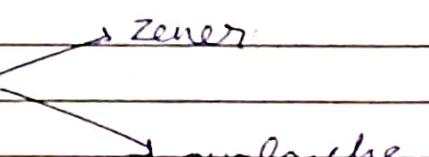
$$I_d = I_s$$

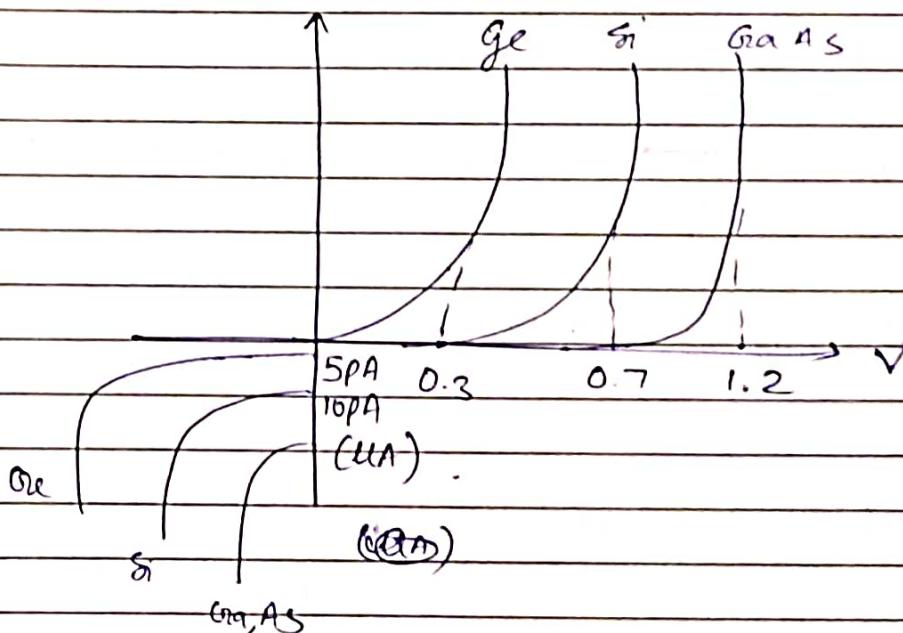
23/12/2020

Junction Diode

$I_{\text{diffusion}}$: it is due to the majority carriers
(in mA)

I_{drift} : It is due to the minority carriers.
(in $\mu\text{A}/\mu\text{A}$)

Types of reverse breakdown 



⑧ Reverse saturation current is the leakage current. (undesirable).

Ge, As \rightarrow higher speed \rightarrow bandwidth.

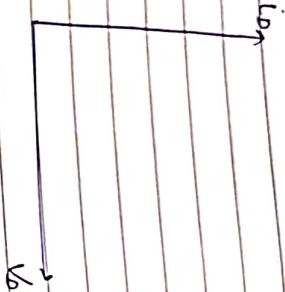
\rightarrow Diode is a non-linear element used in circuits.

$I_s \rightarrow$ Reverse saturation current, (leakage current).

→ Ideal Diode ($V_S = 0$)



= Reverse Bias - open circuit



\rightarrow Resistance = ∞

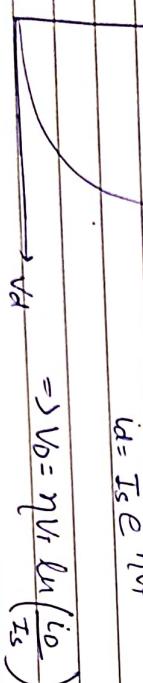
= Forward Bias - closed circuit

\rightarrow Resistance = 0Ω

→ Modelling of Diode

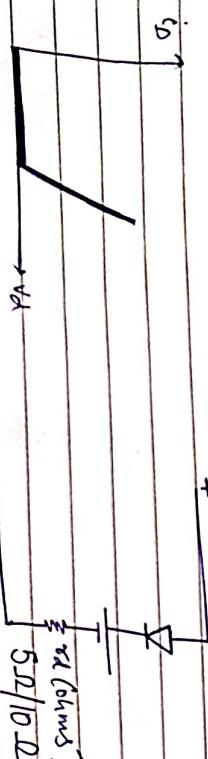
i) Exponential

$$i_d \uparrow$$



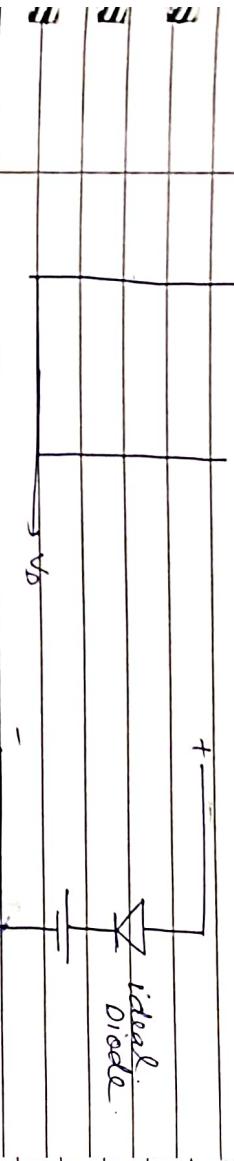
$$i_d = I_S e^{\frac{V_d}{nV_T}}$$

2) Piece-wise Linear Approximation



3) Constant Voltage drop model:

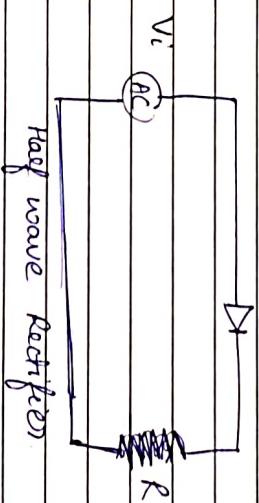
No Resistance Applied



CUTTER CIRCUITS:

(LIMITER CIRCUITS), used to change the appearance of signal

→ Clip away a portion of input signal without disturbing the remaining part of the input signal



Half wave Rectifier

+ve half cycle → Diode in F.B

$V_o = V_{imax}$

-ve half cycle → Diode in R.B → OFF
 $V_o = 0$

$+V_m$

$-V_m$

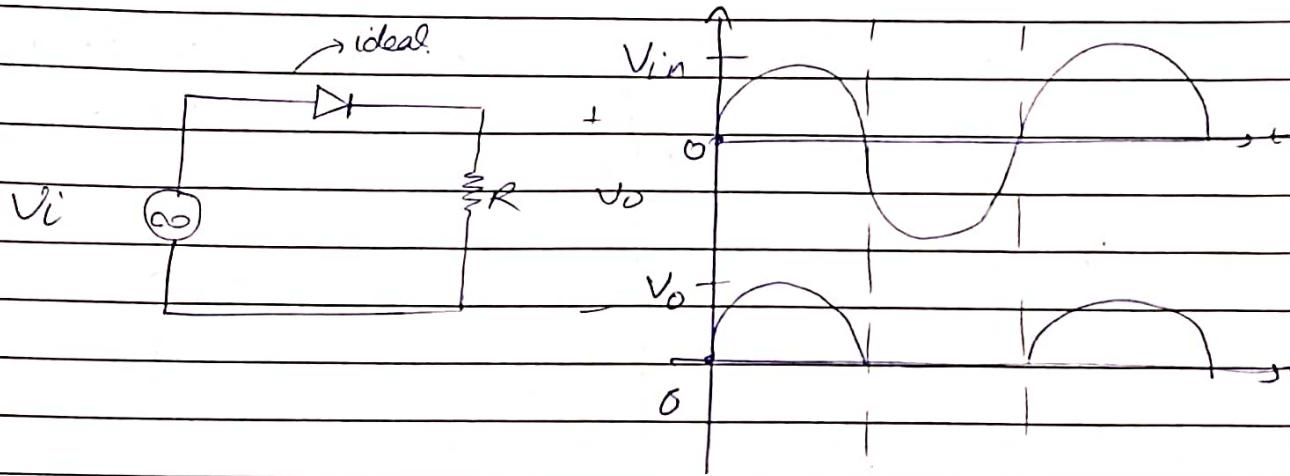
AFTER
RECTIFICATION
(+ve clipper)

AFTER
RECTIFICATION
(+ve clipper)

24/12/2020

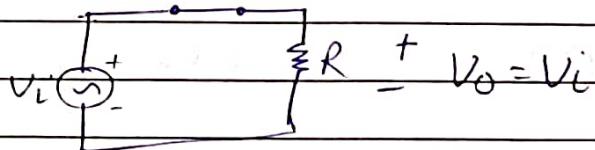
Clippers.

1. Negative Clipper \Rightarrow Clip-ve



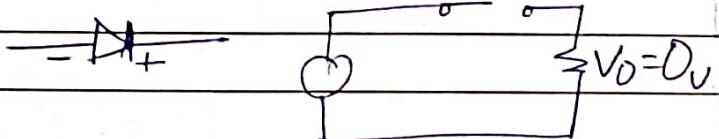
→ +ve half $\rightarrow V_{in} > 0 \rightarrow D$

D \rightarrow F.B $\rightarrow S.C \text{ ON}$
short circ.

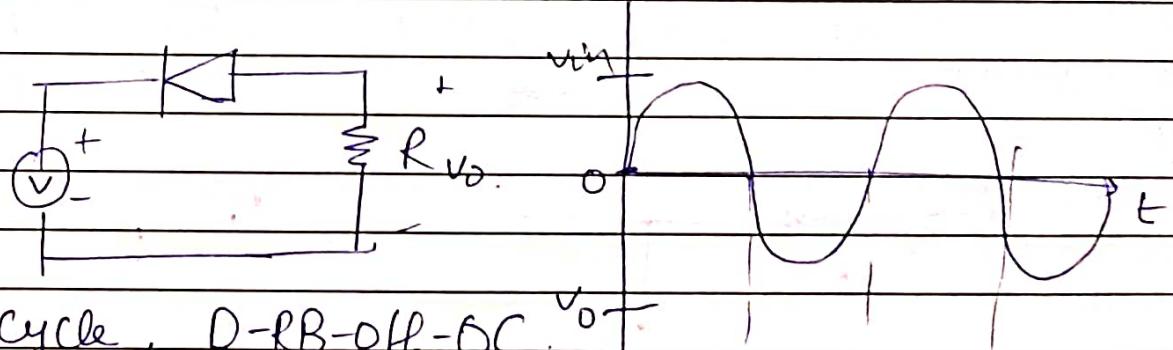


→ -ve half $\rightarrow V_{in} < 0 \rightarrow D$

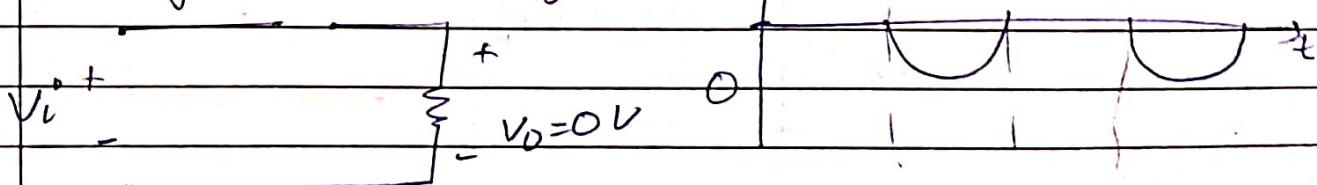
D \rightarrow RB-off $\rightarrow O.C$
open circuit



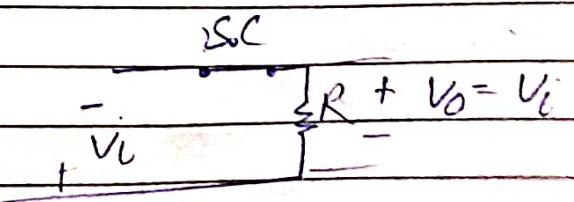
②



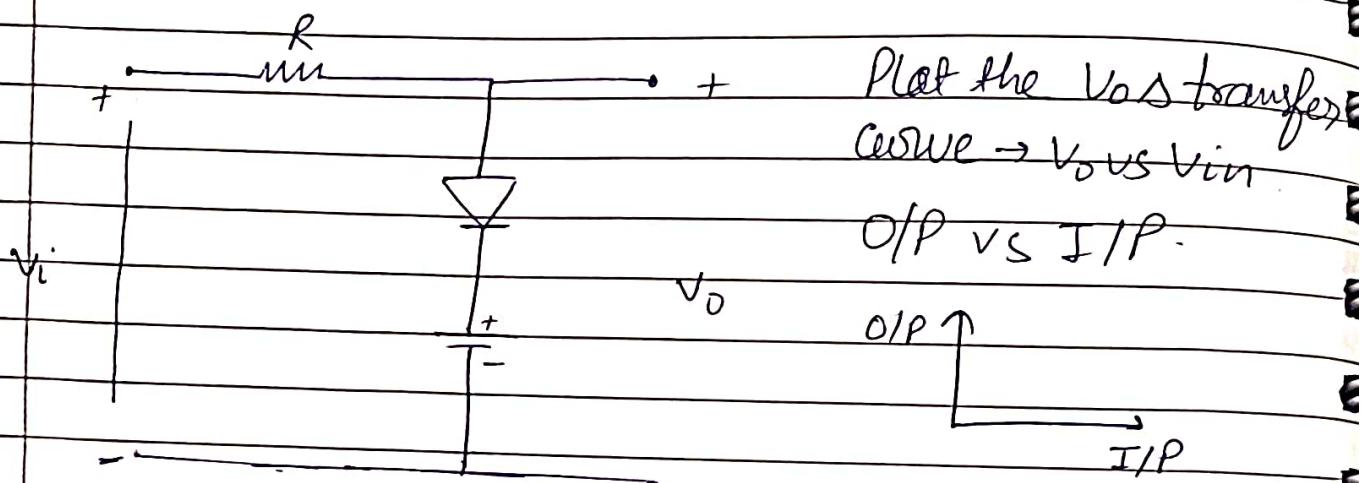
+ve cycle, D-RB-off-OC



-ve cycle, D \rightarrow FB, $\Rightarrow O.V = S.C$



③ Biased clipper : use of DC battery voltage

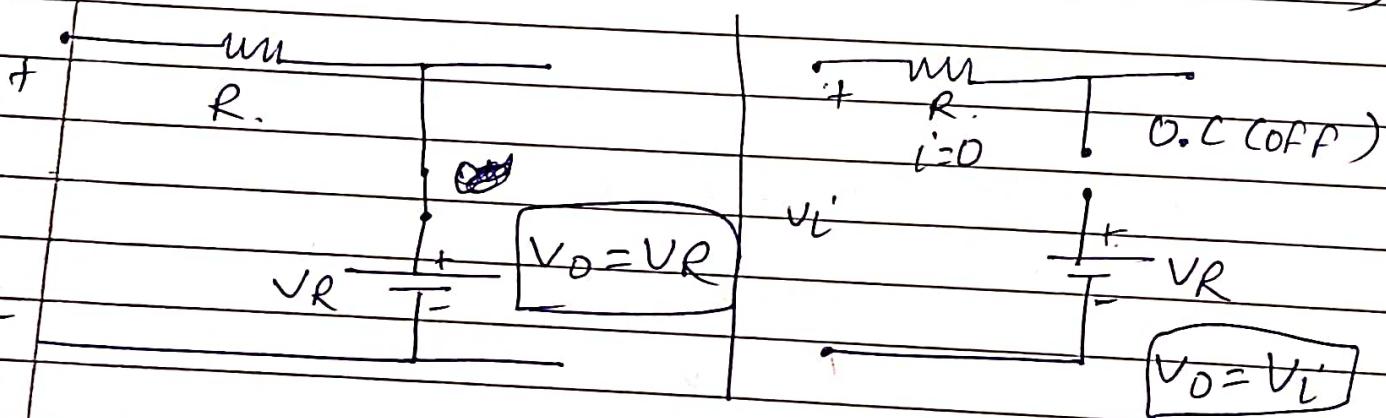


DRB $\longrightarrow V_R$
 Diode Rev Bias.

+ve cycle :-

$D \rightarrow FB$ by $V_i > VR$

when $V_i > VR \Rightarrow D FB$ (S.C) (short circuit)
 $V_i < VR \Rightarrow DRB$ (O.C) (open circuit)

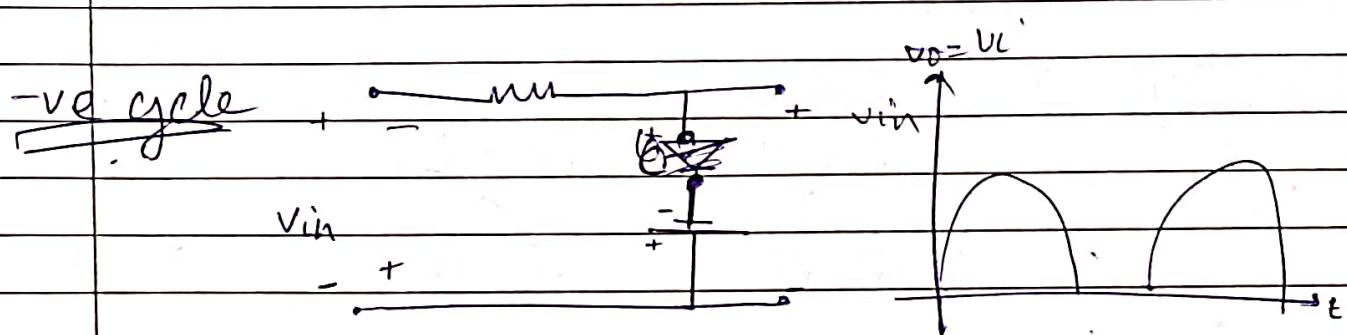
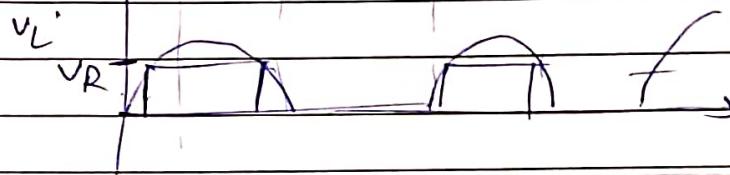


+ve half cycle

$D \rightarrow RB$ by $V_i > VR$

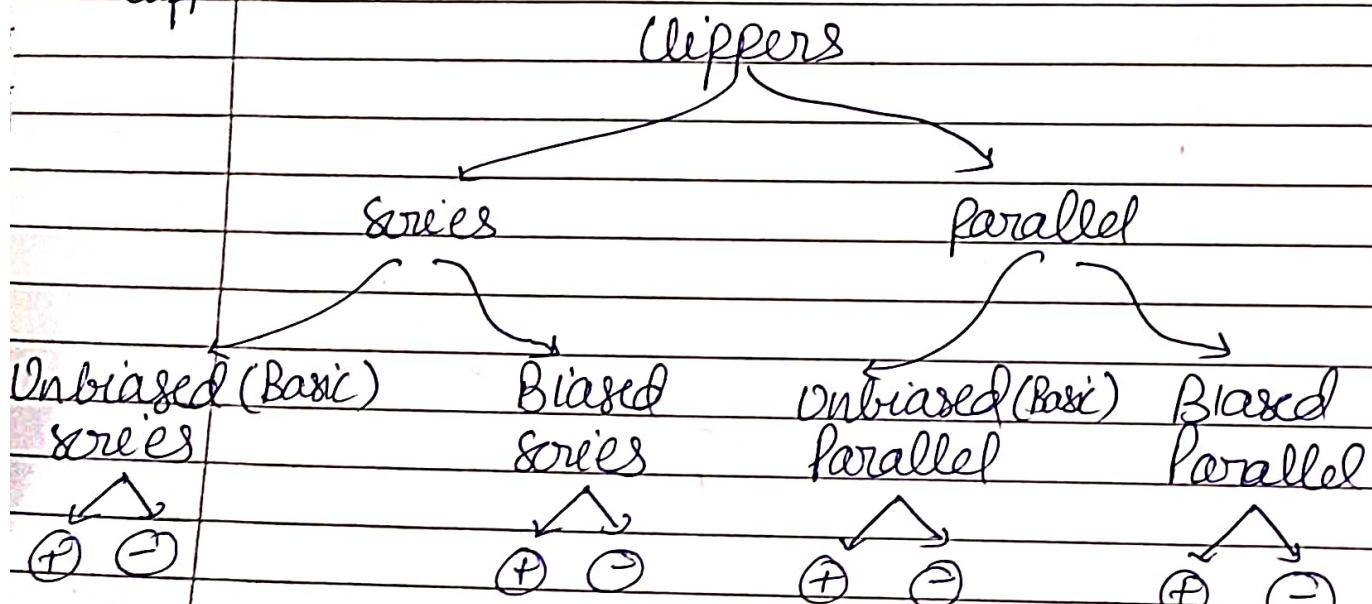
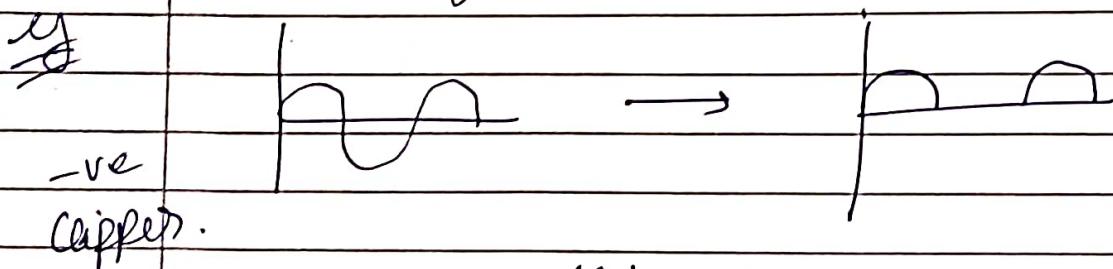
$$D_{on} \rightarrow v_o = v_R \quad v_L > v_R$$

$$D_{off} \rightarrow v_o = v_i \quad v_L < v_R$$

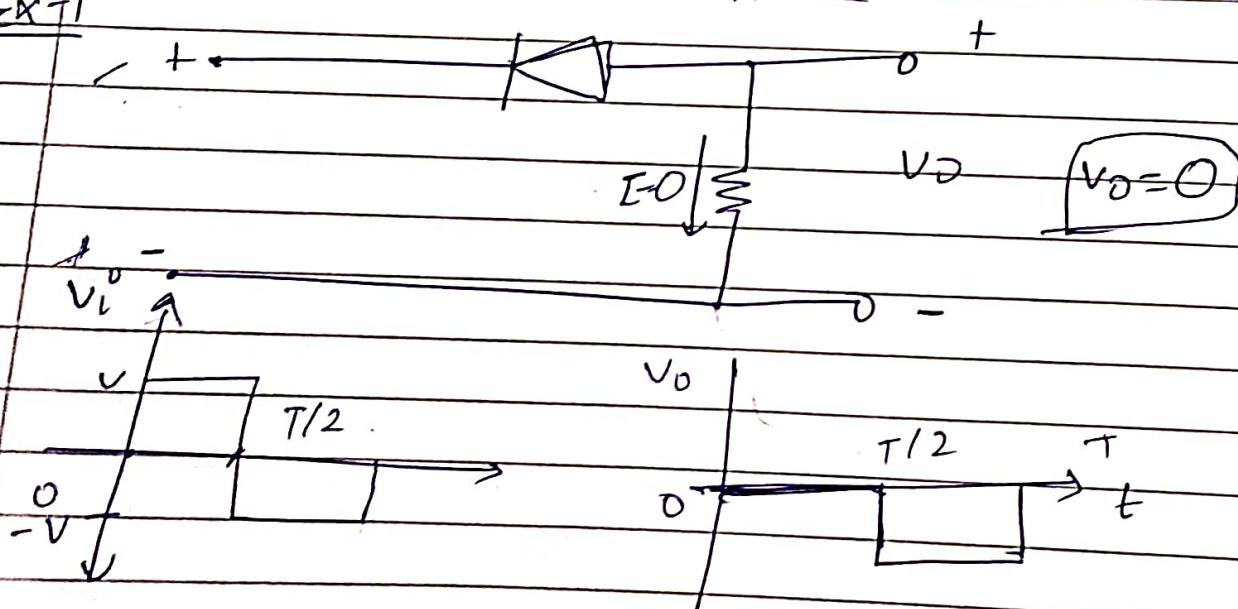


CLIPPERS

Clippers are networks that use diodes to clip a portion of input signal without distorting the remaining part of the waveform.



Ex-1



— / —

For +ve half cycle

for -ve half cycle

Diode \rightarrow R.B (O.C)

Diode \rightarrow F.B (S.C)

$$V_O = 0$$

$$-V_i + V_O = 0$$

$$I = 0$$

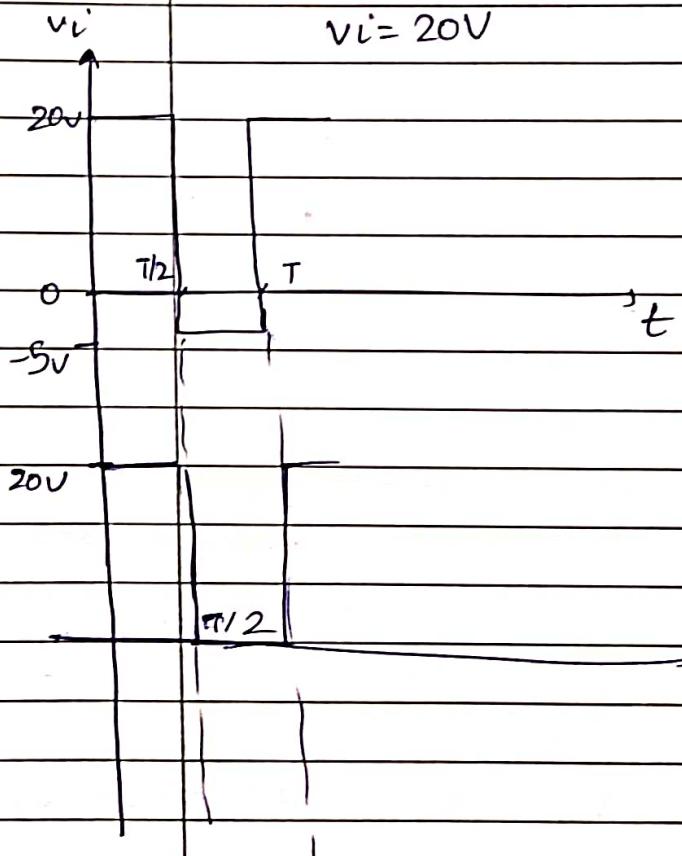
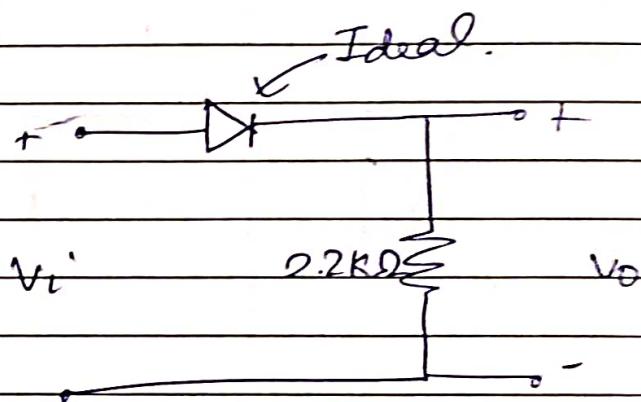
$$V_O = V_i$$

$$\boxed{V_O = -V}$$

So it's

Series Clipper
Unbiased Clipper.
+ve Clipper

Unbiased series Clippers :-



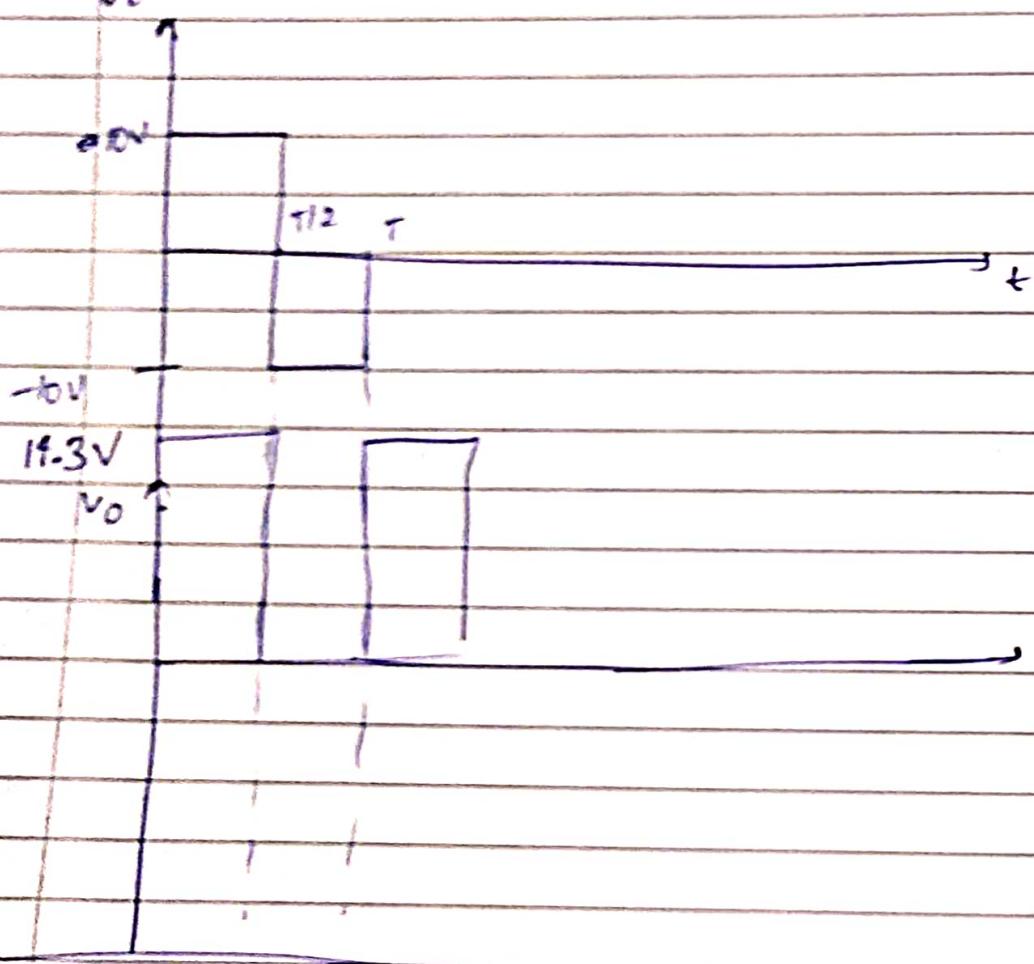
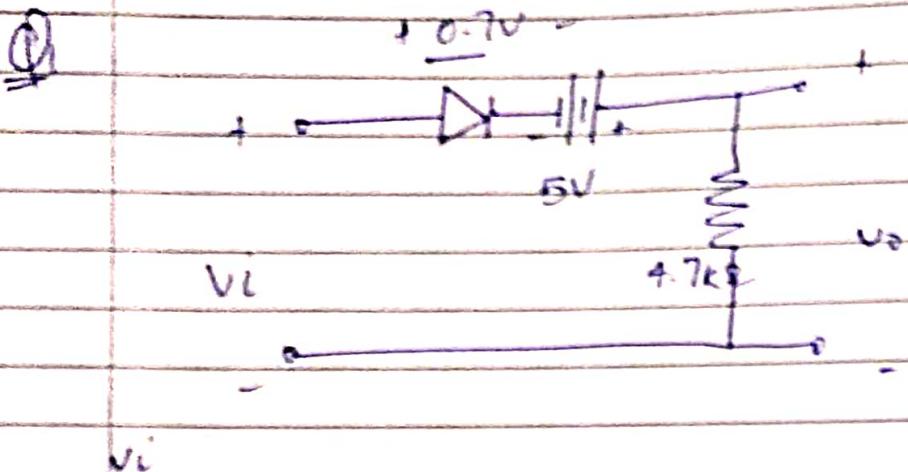
+ve half cycle -ve half cycle
S.C., F.B O.C., R.B

$$V_O = V_i$$

$$V_O = 0$$

-ve Unbiased Clipper Circuit

Biased series Clipper



So 5V battery is FB.

For +ve cycle

$V_i > 5\text{V}$ is FB

$$V_o = V_i - 0.7 + 5\text{V}$$

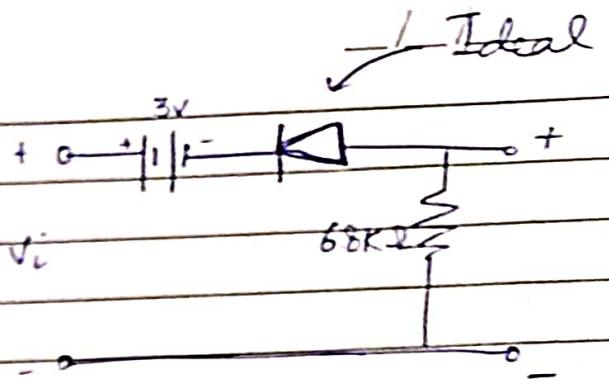
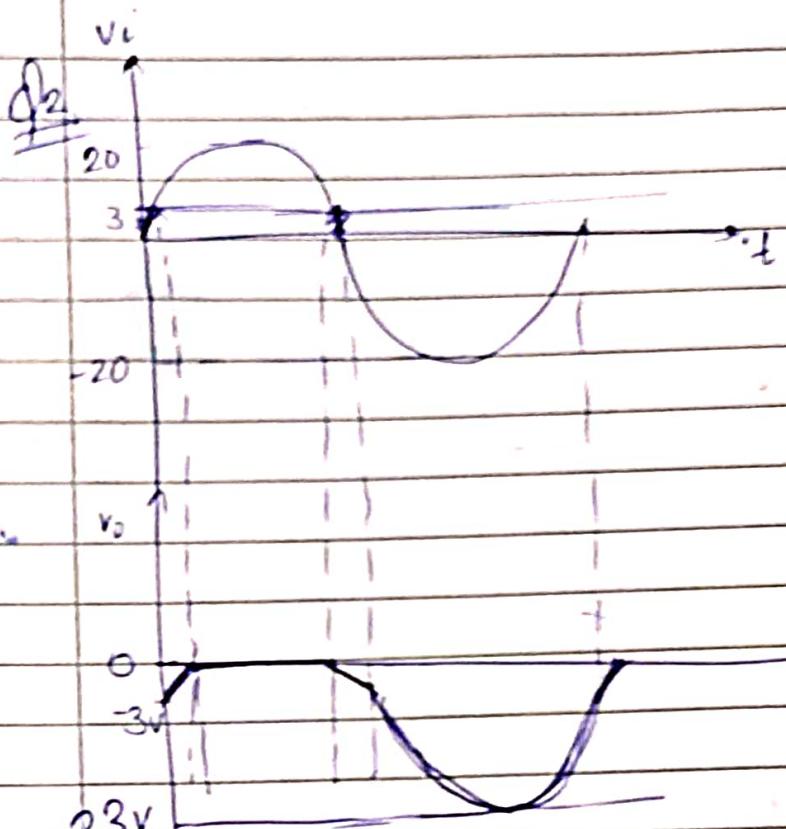
$$= 10 - 0.7 + 5$$

$$V_o = 14.3\text{V}$$

For -ve cycle

$$V_o = 0\text{V} \quad \text{As } 5\text{V} \leq V_i$$

-ve, clipper based.



~~For half cycle (F.B & C.C)~~

~~-ve half~~

~~Q-8-26-20~~

For V_{O3} F.B \rightarrow if $V_i < 3v$. (S.C) $V_o = V_i - 3v$

R.B \rightarrow if $V_i > 3v$ (O.C) $V_o = 0v$

~~-ve half~~ F.B \rightarrow for all values of V_i
(C.S.C)

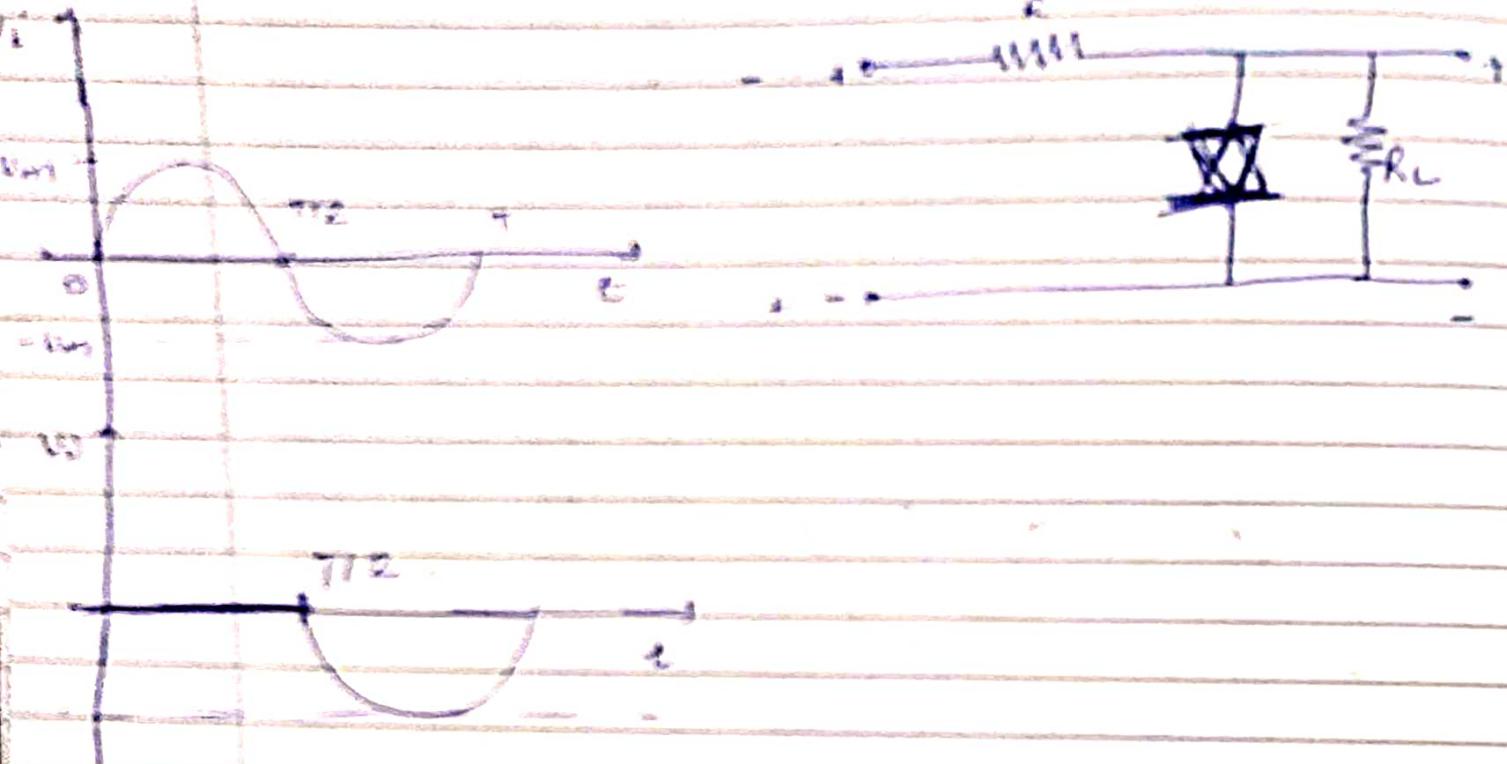
$$V_o + 3 + V_i = 0$$

$$\boxed{V_o = -V_i - 3}$$

$$\underline{V_i=0 \quad V_o=-3 \text{ volts}}$$

$$\underline{V_i=20 \quad V_o=-23 \text{ volts}}$$

#. Diode based parallel Clippers



for two half cycles (RBSCL)
0 to $\pi/2$

$$V_o = 0 \text{ (Assumption on } R_L)$$

for negative cycle ($\pi/2$ to π)

$$+V_L + V_o - V_R = 0$$

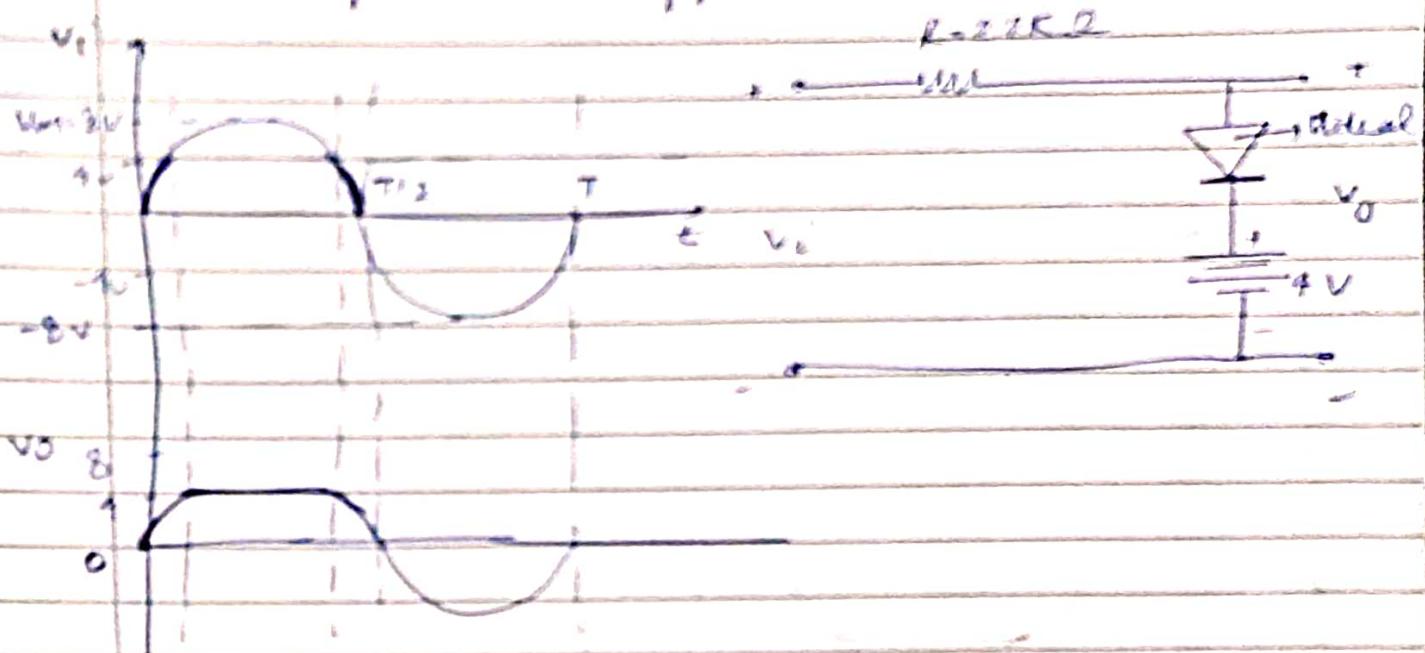
$$V_o = -V_L + V_R$$

$$V_R \approx 0$$

$$V_o = -V_L$$

Positive Clipper circuit.

Biased parallel clippers



Positive half cycle

$V_i > 4$ (FB SC.)

$V_i < 4$ (RB OC)

$V_o = 4V$

* $V_i > 4$ (FB).

$V_o = 4V$

* $V_i < 4$ (RB) (O.C.)

$V_o = V_i$

for -ve half cycle

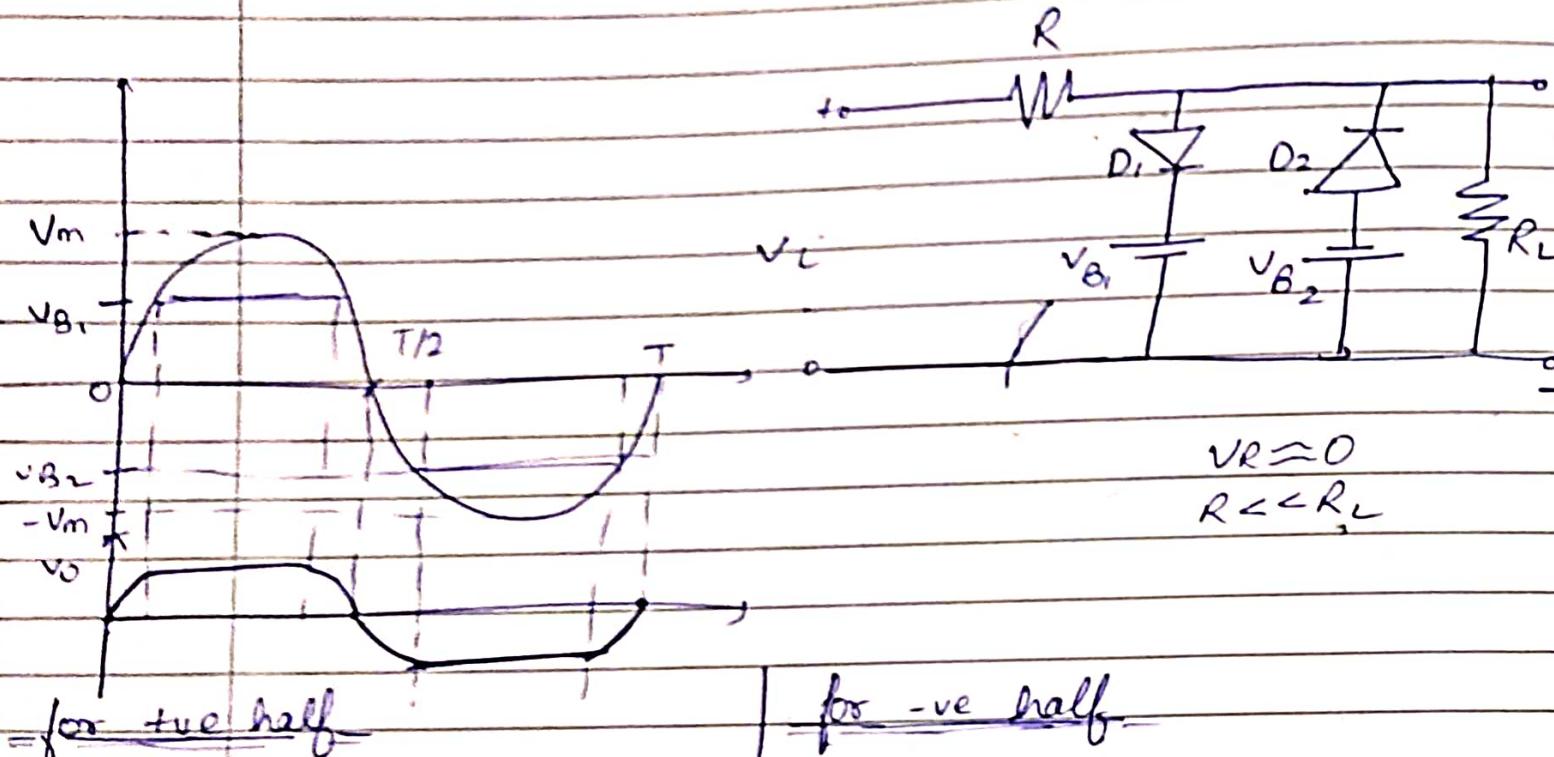
for all V_i :
(RB) (O.C.)

$V_o = V_i$

$V_i > V_o$
 $V_i > -V_2$

Combination Clipper Circuit

Based on Clipper
Biased - ve clipper



$D_2 \rightarrow \text{r.b (O.C)}$

$D_1 \rightarrow \text{r.b by } V_{B_1}$

F.B by V_{B_1}

$D_1 \rightarrow \text{r.b (O.C)}$

$D_2 \rightarrow \text{r.b by } V_{B_2}$

F.B by V_i

$V_i < V_{B_1}$

$V_i > V_{B_1}$

$V_i < V_{B_2}$

$V_i > V_{B_2}$

$D_1 \rightarrow \text{r.b}$

$D_1 \rightarrow \text{F.B}$

$D_1 \rightarrow \text{R.B}$

$D_1 \rightarrow \text{R.B}$

$D_2 \rightarrow \text{r.b}$

$D_2 \rightarrow \text{r.b}$

$D_2 \rightarrow \text{R.B}$

$D_2 \rightarrow \text{F.B}$

$$V_O = V_i$$

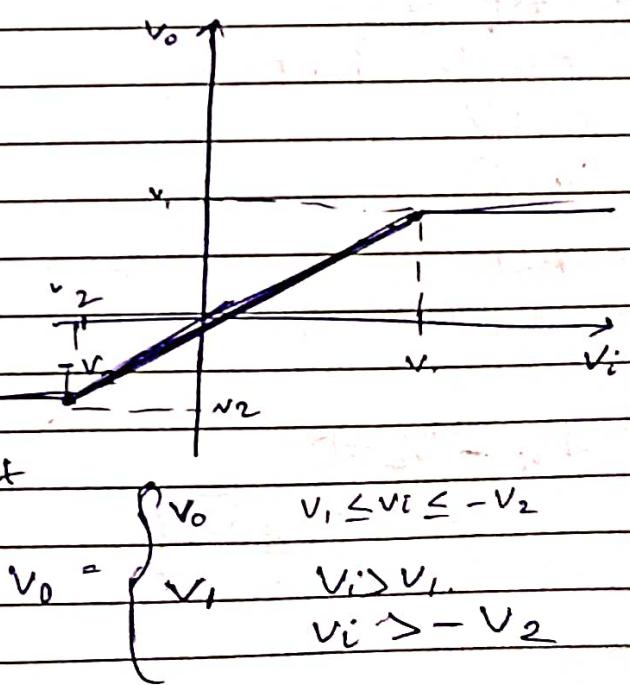
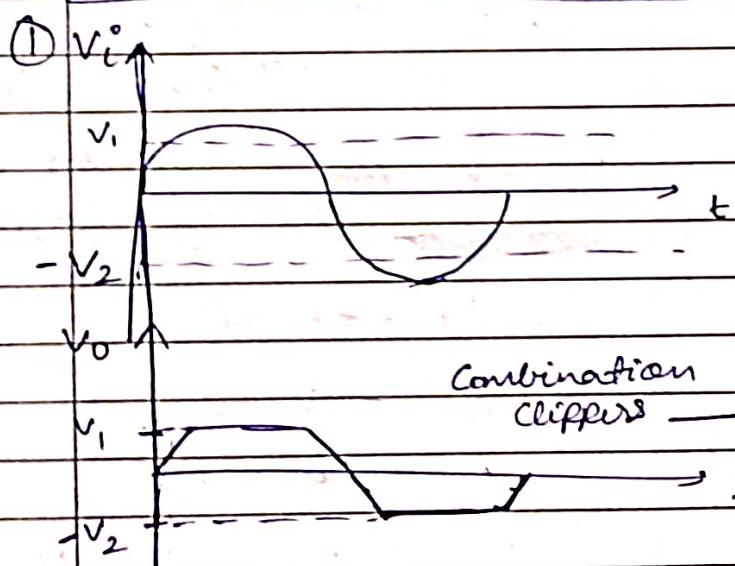
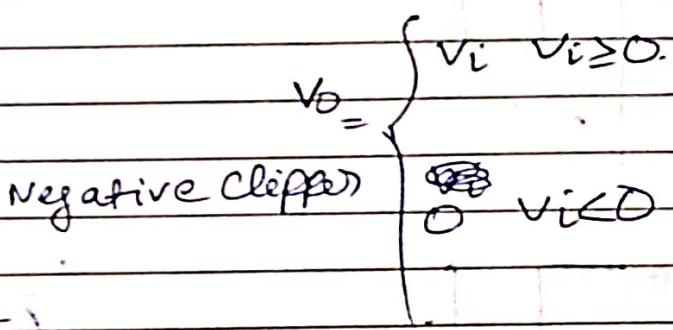
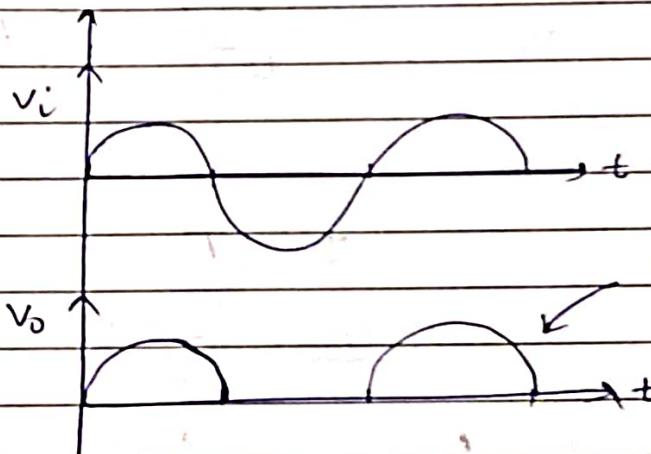
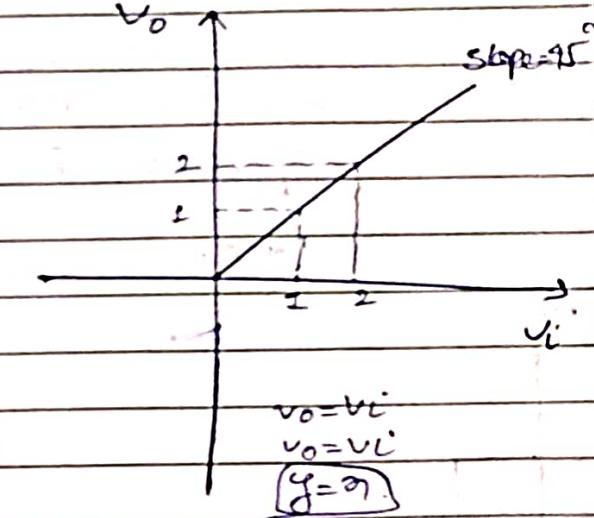
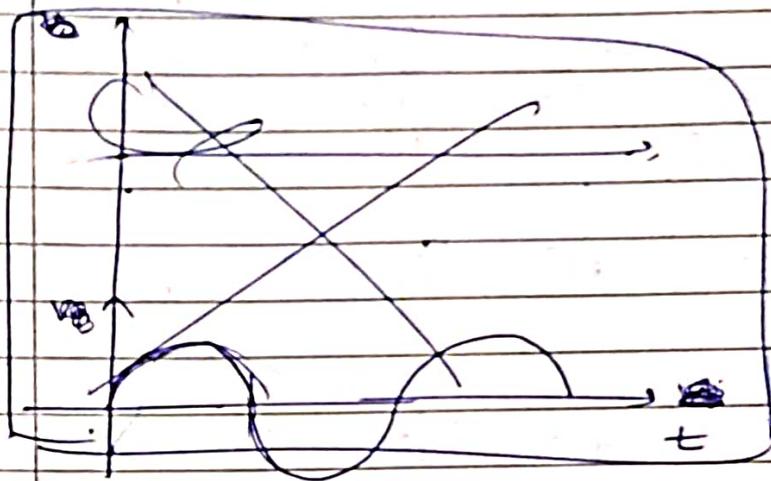
$$V_O = V_{B_1}$$

$$V_O = V_i$$

$$V_O = V_{B_2}$$

Transfer Characteristics of Clipping Circuits

T.C is graph b/w i/p voltage and o/p voltage.

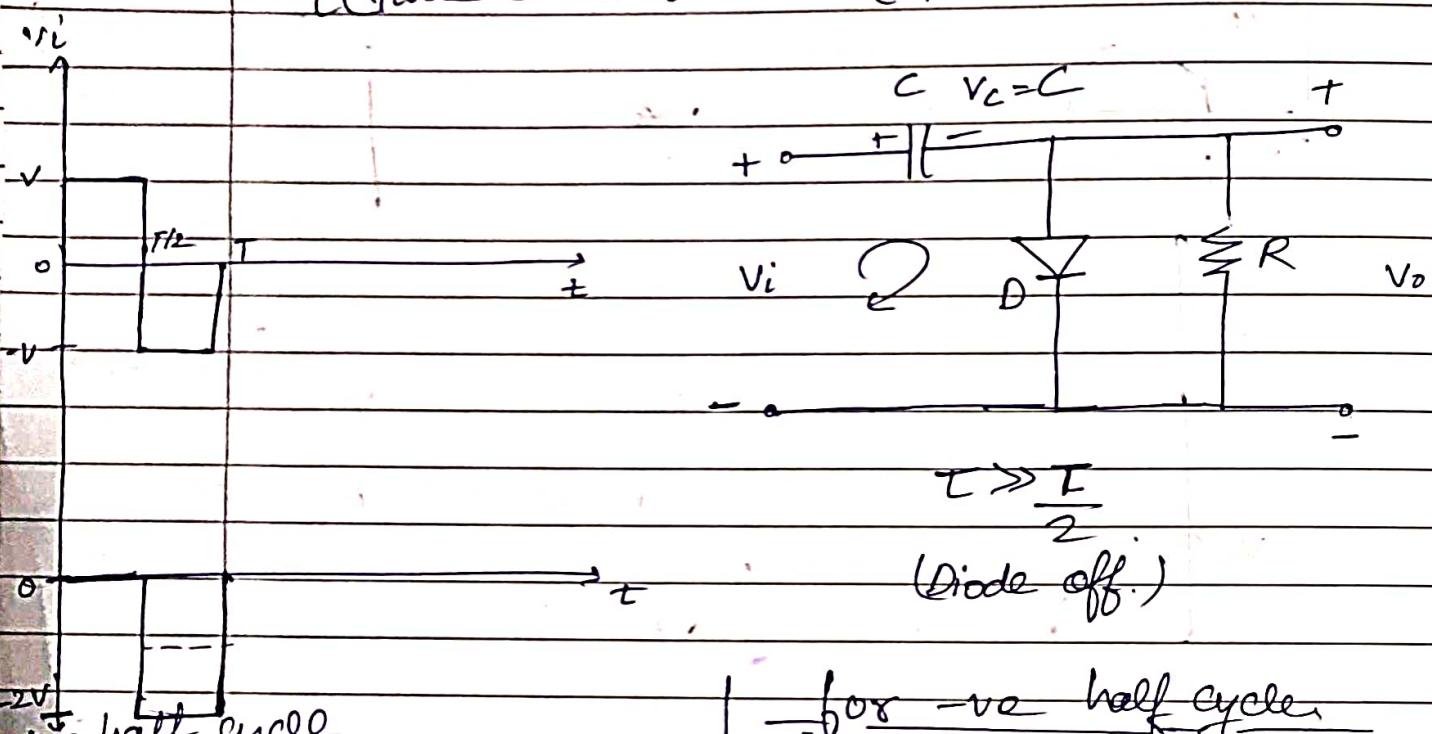


11

Introduction to Clamper

Clamper: A clamper is a network constructed of a diode, a resistor and a capacitor that shifts the waveform to a different dc level without changing the appearance of the applied signal.

$$T(\text{time constant}) = RC \quad (\text{Capacitor charges in } ST)$$



$$0 \rightarrow T/2 \rightarrow (\text{D.F.B})(\text{S.C})$$

$$v_i = +V$$

$$v_o = 0$$

$$R = 0$$

$$T = 0$$

$$T = RC$$

$$+V_i - V_c = 0$$

$$V_c = V_i = +V$$

$$\text{for -ve half cycle} \\ T/2 \rightarrow T (\text{D.R.B}) (\text{O.C})$$

$$V_i = -V \quad \text{now the capacitor is already charged}$$

$$+V_i + V_o + V_c = 0$$

$$V_o = -(V_i + V_c)$$

$$V_o = -(-V + V_c)$$

$$V_o = (V - V_c) \quad (V_c = V, \text{ also})$$

$$V_o = -V - V$$

$$\boxed{V_o = -2V}$$

NOTE) v_o rms remains same

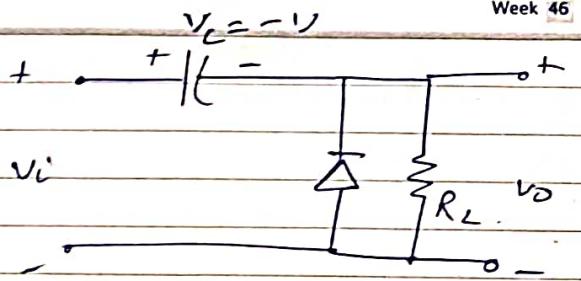
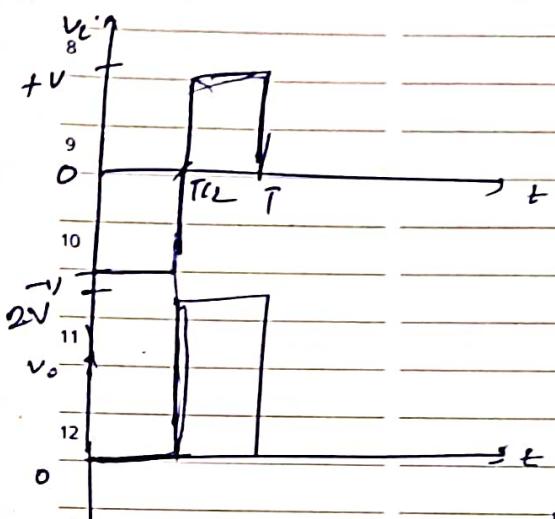
\Rightarrow Peak value changes.

Positive & Negative Clamper Circuits :

17

321-044
Friday

Week 46



$$0 \rightarrow T/2$$

$$v_c = -V$$

$$v_o = 0$$

$$v_i - v_c = 0$$

$$v_c = v_i = -V$$

$$T/2 \rightarrow T$$

$$v_c = +V$$

•

$$v_o + v_c - v_i = 0$$

$$v_o = v_i - v_c$$

$$v_o = +V - (-V)$$

$$\boxed{v_o = 2V}$$

~~$v_o = 0$~~ $v_o = V$ (v_i is $+ve$)

~~$v_o = 0$~~

$$T/2 \quad T$$

$$v_c = +V$$

$$v_o = v_c - v_i$$

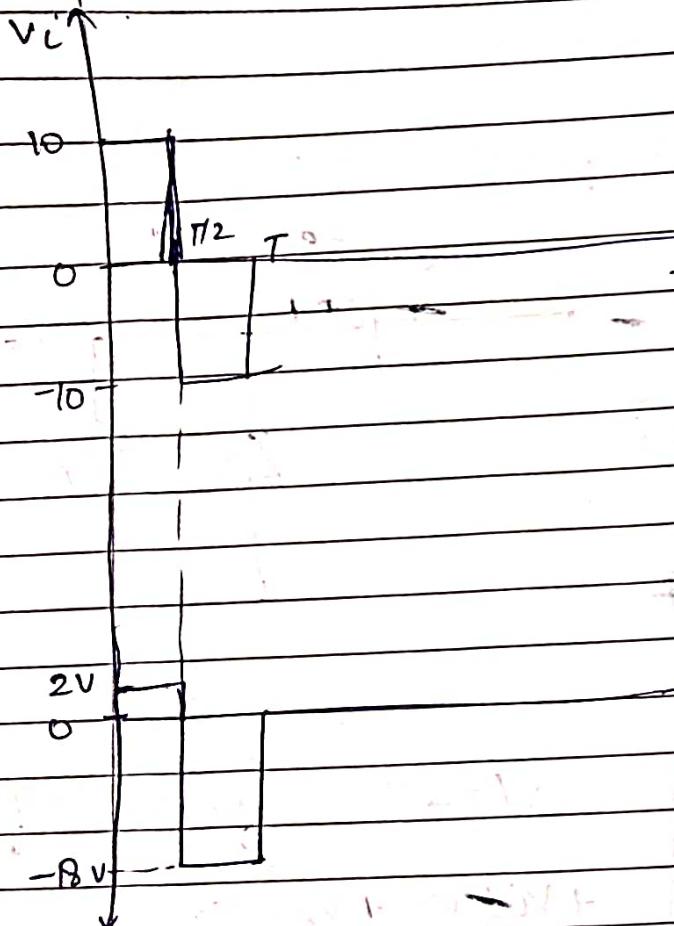
$$v_o = V - (-V)$$

$$\boxed{v_o = 2V}$$

(Additional Voltage swing)

Biased-Clampes Circuit

~~Ex.~~



for $0 \rightarrow T/2$

$$V_i = +10V \text{ (F.B./SC)}$$

$$+V_i - V_C - 2 = 0$$

$$V_C = V_i - 2$$

$$V_C = 10 - 2$$

$$\boxed{V_C = 8V}$$

$T/2 \rightarrow T$

$$V_i = -10V \text{ (O.C.)}$$

$$+V_i - V_C - V_o = 0$$

$$V_o = V_i - V_C$$

$$V_o = -10 - (8)$$

$$\boxed{V_o = 18V}$$

$$+V_i - V_C - V_o = 0$$

$$V_o = V_i - V_C$$

$$\boxed{V_o = 10 - 8}$$

$$\boxed{V_o = 2V}$$

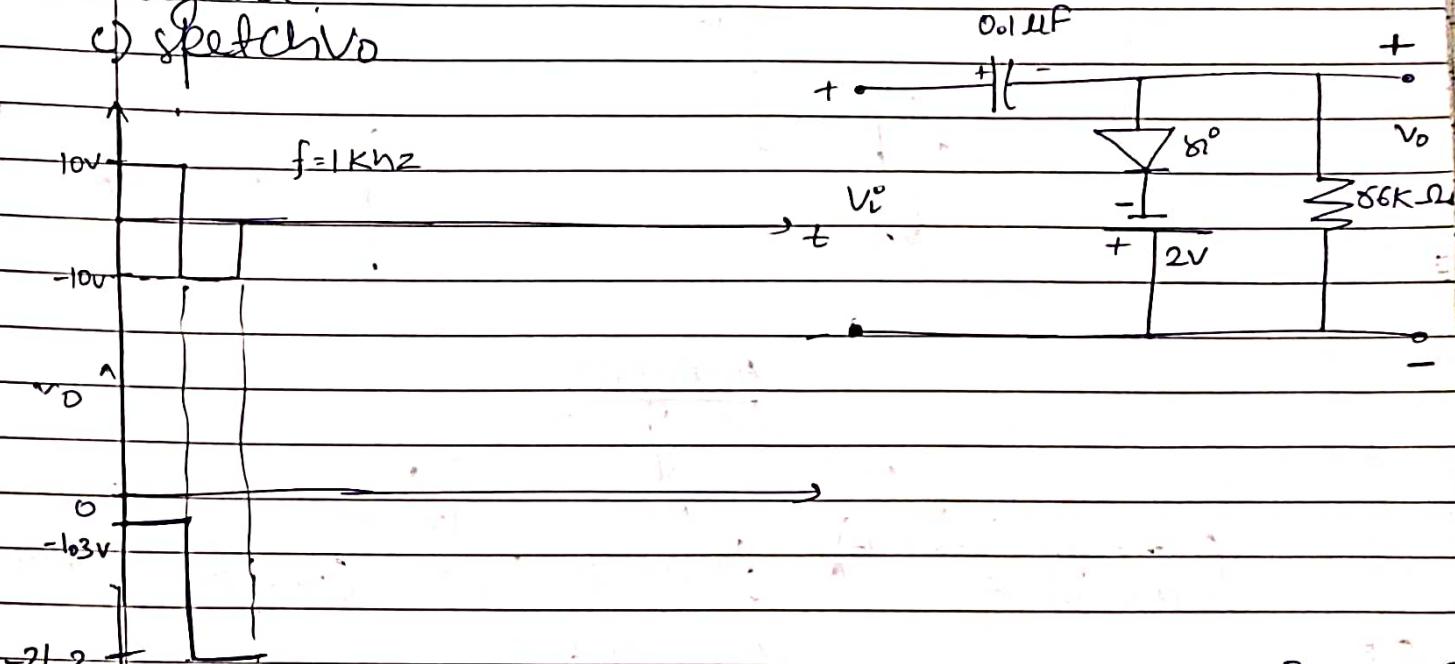
Q)

For the network in figure

a) calculate δT

b) compare δT to half the period of the applied signal

c) sketch



a) $T = RC = 86 \times 10^3 \times 0.1 \times 10^{-6} = 8.6 \times 10^{-3} \Rightarrow T = 8.6 \times 10^{-3} = 2.8 \times 10^{-3}$

b) $T = \frac{1}{f} \text{ sec} = \frac{1}{1 \times 10^3} \text{ sec} = 10^{-3} \text{ sec} = 1 \text{ mS} \quad \frac{T}{2} = 0.5 \text{ msec}$
 $\delta T > T/2$

c) +ve half cycle
F.B / S.C

$$+V_i - V_c = 10$$

-ve half cycle

$$V_L = -10$$

$$+V_i - V_L - V_C - V_o = 0$$

$$-0.7 +V_i - V_C + 2 = 0$$

$$V_C - V_i + 2 \Rightarrow \boxed{V_C = 10.3 \text{ V}}$$

$$+V_i - V_C - V_o = 0$$

$$V_o = V_i - V_C$$

$$= 10 - 10.3$$

$$\boxed{V_o = -0.3}$$

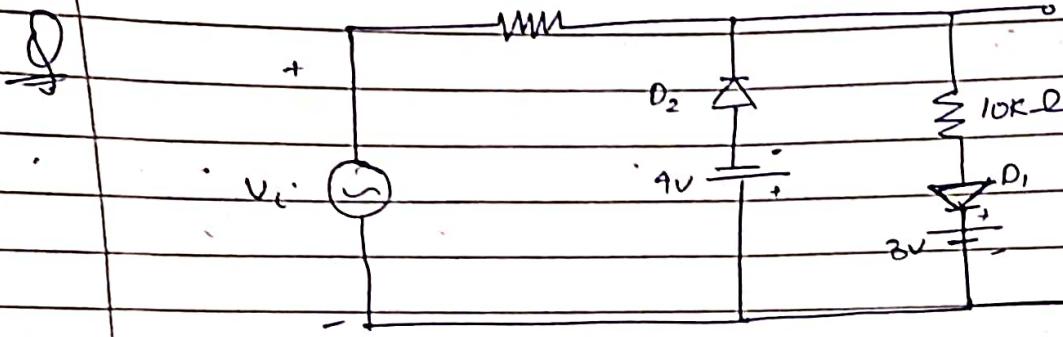
$$\boxed{V_o = -1.3 \text{ V}}$$

$$V_o = V_i - V_C$$

$$V_o = -10 - 10.3$$

$$\boxed{V_o = -20.3}$$

$$\boxed{V_o = -21.3 \text{ V}}$$



(a) For ideal diode.

(b) For practical diode (0.7)

(i) For +ve half

$D_2 \rightarrow R.B.$

$D_1 \rightarrow F.B \quad V_i > 3$

R.B $V_i < 3$

For -ve half

$D_1 \rightarrow R.B$

$D_2 \rightarrow R.B \quad V_i < 4$

F.B $V_i > 4$

$V_i > 3$

$D_1(\text{ON}) \quad D_2(\text{OFF})$

$$V_o = V_i - 3 = 0$$

$$V_o = V_i + 3.$$

$$V_o = \frac{V_i - 3}{10k\Omega} \times 10k\Omega + 3.$$

$$\boxed{V_o = \frac{2}{3} V_i + 1}$$

$V_i < 3$

$D_1, D_2(\text{OFF})$

$$V_o + V_R - V_i = 0$$

$$V_o = V_i - V_R \quad (V_R \approx 0)$$

$$V_o = V_i -$$

$\underline{V_i > 4}$
 $\underline{D_2(\text{ON}) \quad D_1(\text{OFF})}$

$$+V_i - 4 = 0$$

$$+V_i = 4$$

$$\boxed{V_o = 4}$$

$\underline{V_i < 4}$
 $\underline{D_1(\text{R.B}) \quad D_2(\text{R.B})}$

$$\boxed{V_o = V_i}$$

For practical diode

For +ve half

$D_2 \rightarrow R.B.$

$D_1 \rightarrow F.B. V_i > 3$

R.B. $V_i < 3$

For -ve half

$D_1 \rightarrow R.B.$

$D_2 \rightarrow R.B. V_i < 4$

F.B. $V_i > 4$

$V_i > 3$

$D_1(F.B) D_2(R.B)$

$$+V_L^o = V_L^o - i(10) - 0.7 - 3 = 0$$

$V_i > 4$

$D_1 \rightarrow R.B (OFF)$

$D_2 \rightarrow F.B (ON)$

$$+V_D + 0.7 + 4 = 0$$

$$V_D = -4.7$$

$$V_D - i(10) - 3 - 0.7 = 0$$

$$V_D = i(10) + 3.7$$

$$V_D = \frac{V_L^o - 3 - 0.7}{15} \times 10 + 3.7$$

$V_i < 4$

$D_1(OFF) D_2(OFF)$

$$V_D = \frac{2(V_L^o - 3.7)}{3} + 3.7$$

$$V_D = V_L^o$$

$$\boxed{V_D = \frac{2}{3} V_L^o + \frac{3.7}{3}}$$

$V_i < 3$

$D_1(R.B) D_2(R.B)$

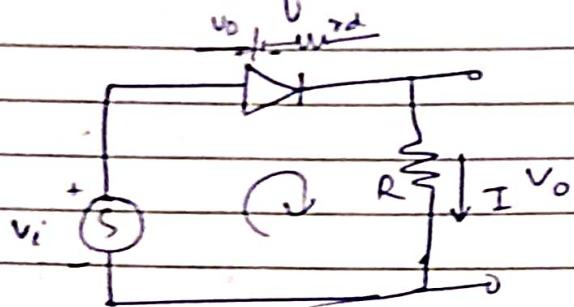
$$\boxed{V_D = V_L^o}$$

50 /12/2020

Rectifier circuit.



Half wave rectified



for two half

$$+V_i^o - V_D - I r_d - IR = 0$$

$$I = \left(\frac{V_i^o - V_D}{r_d + R} \right)$$

$$V_D = V_R$$

$$V_D = V_R$$

$$V_D = IR = \left(\frac{V_i^o - V_D}{r_d + R} \right) R$$

$$\Rightarrow V_D = \left(\frac{R}{r_d + R} \right) V_i^o - \left(\frac{R}{r_d + R} \right) V_D$$

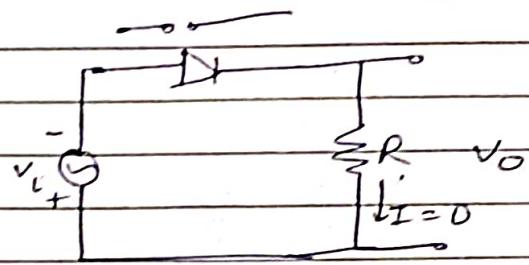
$$r_d \ll R$$

$$\Rightarrow V_D = V_i^o - V_D$$

$$V_D = 0.7V \rightarrow s_1 \\ = 0.3V - V_D$$

for +ve half

$$V_O = 0$$



$$V_L$$

$$V_m$$

$$V_0$$

$$V_m$$

$$V_0$$

$$\text{Avg. O/P voltage } \omega t - (0 \rightarrow \pi) \quad V_O = V_m \sin \omega t$$

$$\omega t - (\pi \rightarrow 2\pi) \quad V_O = 0$$

$$V_{avg} = \frac{1}{2\pi} \int_0^{2\pi} V_O d(\omega t) \Rightarrow \frac{1}{2\pi} \left[\int_0^{\pi} V_m \sin \omega t d(\omega t) + \int_{\pi}^{2\pi} 0 d(\omega t) \right]$$

$$\Rightarrow \frac{1}{2\pi} \int_0^{\pi} V_m \sin \omega t d(\omega t)$$

$$\Rightarrow \frac{V_m}{2\pi} [-\cos \omega t]_0^{\pi} \Rightarrow \frac{V_m}{2\pi} [-\cos \pi - (-\cos 0)]$$

$$V_O = V_L - V_D$$

$V_L < V_D$ (OFF).

$$V_O = 0 \quad V_L < V_D$$

$$V_O = V_L - V_D \quad V_L > V_D$$

Ideal model.

$$V_O = 0$$

$$V_O = V_L \quad \text{--- +ve half}$$

$$V_O = 0 \quad \text{--- -ve half}$$

$$\Rightarrow \frac{V_m}{2\pi} \times 2$$

$$V_{avg} = \frac{V_m}{\pi} = 0.318 V_m$$

$$V_{avg} = 0.318 V_m$$

* Avg. Load Current:

$$I_{avg} = \frac{V_{avg}}{R} = \frac{V_m}{\pi R}$$

$$I_{avg} = \frac{V_m}{\pi R} = \frac{I_m}{\pi}$$

$$I_{avg} = 0.318 \pi$$

* RMS Load Current

$$I_{rms} = \sqrt{\frac{\int_0^{2\pi} I^2 d(\omega t)}{\int_0^{2\pi} d(\omega t)}}$$

$$\Rightarrow \sqrt{\frac{1}{2\pi} \int_0^{2\pi} I^2 d(\omega t)}$$

$$\Rightarrow \left[\frac{1}{2\pi} \cdot \left(\int_0^{2\pi} I_m^2 \sin^2 \omega t d(\omega t) + \int_0^{2\pi} I_o d(\omega t) \right) \right]^{1/2}$$

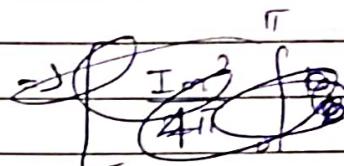
$$I = I_m \sin \omega t \quad 0 < \omega t < \pi$$

$$I_o = 0 \quad \pi < \omega t < 2\pi$$

* RMS value is equivalent to DC current.
Bulb connected to 5V AC or 5V DC shines same brightness

$$\Rightarrow \left[\frac{1}{2\pi} \int_0^{\pi} I_m^2 \sin^2 \omega t d(\omega t) \right]^{\frac{1}{2}}$$

$$\Rightarrow \left[\frac{I_m^2}{2\pi} \int_0^{\pi} \frac{1 - \cos(2\omega t)}{2} d(\omega t) \right]^{\frac{1}{2}}$$



$$\Rightarrow \left[\frac{I_m^2}{4\pi} \left(\omega t - \frac{\sin 2\omega t}{2} \right)_0^{\pi} \right]^{\frac{1}{2}}$$

$$\Rightarrow \left[\frac{I_m^2}{4\pi} ((\pi - 0) - 0) \right]^{\frac{1}{2}}$$

$$\Rightarrow \left(\frac{I_m^2}{4} \right)^{\frac{1}{2}} = \frac{I_m}{2}$$

$I_{rms} = \frac{I_m}{2}$

$$V_{rms} = I_{rms} R$$

$$V_{rms} = \frac{I_m R}{2}$$

$$V_{rms} = \frac{(I_m R)}{2}$$

$V_{rms} = \frac{V_m}{2}$

γ = rms value of AC component of output
over value of output

$$I = I_{AC} + I_{DC} \Rightarrow I_{AC} = I - I_{DC}$$

$$I_{AC\text{ rms}} = \sqrt{\frac{1}{2\pi}} \int_{-\pi}^{\pi} I_{AC} d(\omega t)$$

$$= \sqrt{\frac{1}{2\pi}} \int_{-\pi}^{\pi} (I - I_{DC})^2 d(\omega t)$$

$$= \sqrt{\frac{1}{2\pi}} \int_0^{2\pi} (I^2 + I_{DC}^2 - 2I \cdot I_{DC}) d\omega t \Big]^\frac{1}{2}$$

$$\approx \sqrt{\frac{1}{2\pi}} \int_0^{2\pi} I^2 d\omega t + \underbrace{\frac{1}{2\pi} \int_0^{2\pi} I_{DC}^2 d\omega t}_{(I_{DC})^2} - \underbrace{\frac{1}{2\pi} \int_0^{2\pi} 2I \cdot I_{DC} d\omega t}_{2I_{DC}}$$

$$= \sqrt{\left[I_{DC}^2 + \frac{I^2 dC}{2\pi} (2\pi - 0) - 2I^2 dC \right]}^\frac{1}{2}$$

$$\Rightarrow \sqrt{I_{DC}^2 - I^2 dC}$$

$$\gamma = \frac{\sqrt{I_{DC}^2 - I^2 dC}}{I_{DC}} = \sqrt{\frac{I_{DC}^2 - I^2 dC}{I^2 dC}}$$

$$\gamma = \sqrt{\frac{I_{DC}^2}{I^2 dC} - 1}^\frac{1}{2}$$

$$\boxed{\gamma = \sqrt{(f \cdot f)^2 - 1} \quad \boxed{f_f = 157 \quad \boxed{f_f = 121\%}}}$$

Form factor is defined as the ratio of rms load voltage and average load voltage.

$$F.F = \frac{V_{rms}}{V_{avg}}$$

For half wave rectifiers

$$F.F = \frac{V_m / 2}{V_m / \pi} = \frac{\pi}{2} = 1.57 \rightarrow 1$$



$$V_{rms} = V_m \quad F.F = \frac{V_m}{V_{avg}} = f \\ V_{avg} = V_m$$

$$V_{avg} = 1.57 V_{avg}$$

Ripple factor: The output current contains both AC & DC components. The ripple factor measures the percentage of AC component in the rectified output.

$$Y = 0 \text{ (ideally)} \quad \text{OR} \quad I_{rms}^2 = I_{ac}^2 + I_{dc}^2$$

$$\text{AC component} \rightarrow Y=0 \quad \gamma = \frac{I_{ac}}{I_{dc}} = \sqrt{\left(\frac{I_{rms}}{I_{dc}}\right)^2 - 1}$$

$$= \sqrt{f.F^2 - 1} \\ \Rightarrow 1.57 \\ \Rightarrow 1.2$$

(Diff b/w Stages of rectifier)

Efficiency: ratio of dc power available at the load to the input ac power.

$$\eta \gamma = \frac{P_{load}}{P_{in}} \times 100\%$$

$$P = VI$$

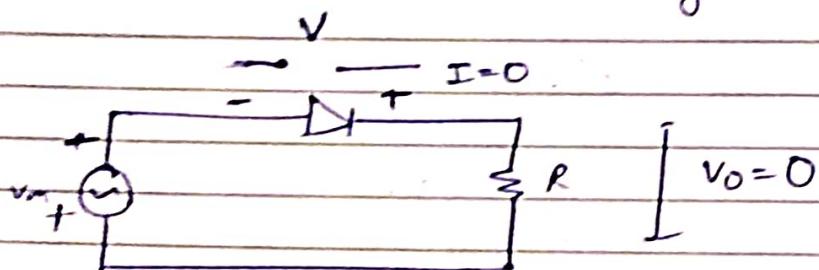
$$P = I^2 R$$

$$= \frac{I^2 d \times R}{I_{rms}^2 \times R} \times 100\%$$

$$= \frac{I_m^2 / \pi^2}{I_m^2 / 4} = \frac{4}{\pi^2} \times 100\%$$

$$[\eta \gamma = 40.56\%]$$

Peak Inverse Voltage (PIV) Maximum reverse bias voltage that can be applied across the diode before entering to the zener or breakdown region.



$$-V_m + V = 0$$

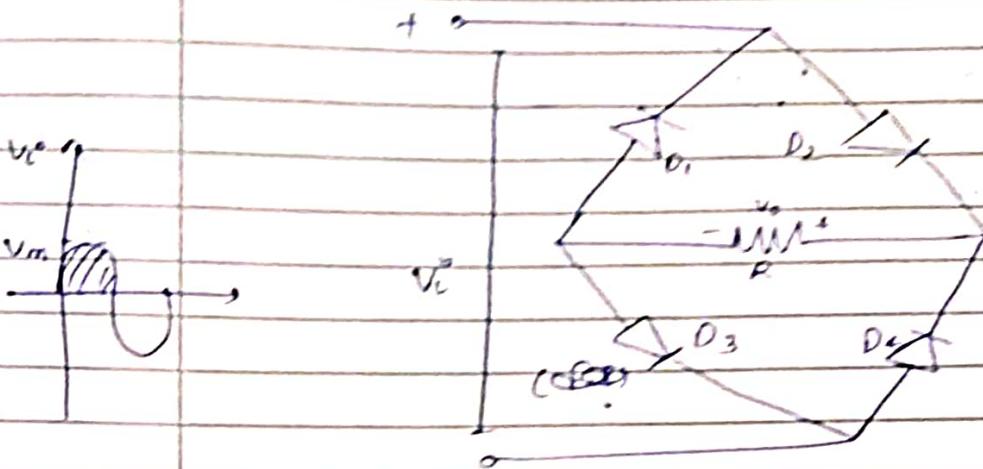
$$V = V_m$$

$$\underline{PIV \geq V_m} \quad \text{As PIV} < V_m \text{ (damage occur)}$$

To protect from damage.

01/12/2020

Full wave-Bridge rectifier



positive half

$D_2, D_3 \rightarrow ON$
 $D_1, D_4 \rightarrow OFF$

$$+V_i^o - V_o = 0$$

$$\underline{V_o = V_i^o} \rightarrow \text{ideal}$$

$$\boxed{V_o = V_i^o - 2V_b} \quad \text{for real (VD)}$$

$$\boxed{V_o = V_i^o - 2V_b - 2I_{rd}} \quad \rightarrow \text{real}$$

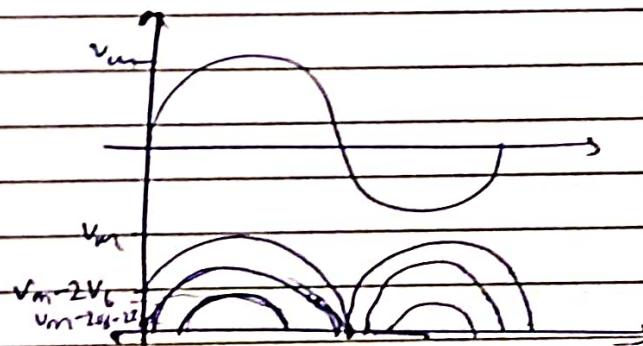
for -ve half

$D_2, D_3 \rightarrow OFF$
 $D_1, D_4 \rightarrow ON$

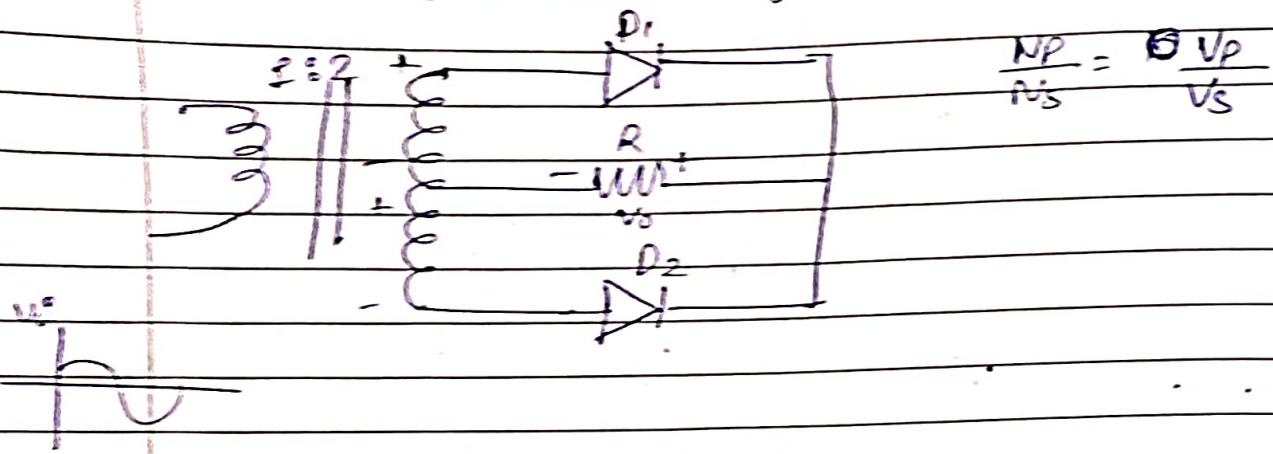
$$V_o = V_i^o$$

$$\boxed{V_o = V_i^o - 2V_b - 2I_{rd}}$$

Current flowing in same direction
 No polarity change at load



full wave - center tapped rectifier



for +ve half cycle

D₁ → ON D₂ → OFF

$$+V_i - V_o = 0.$$

$$\boxed{V_o = V_i}$$

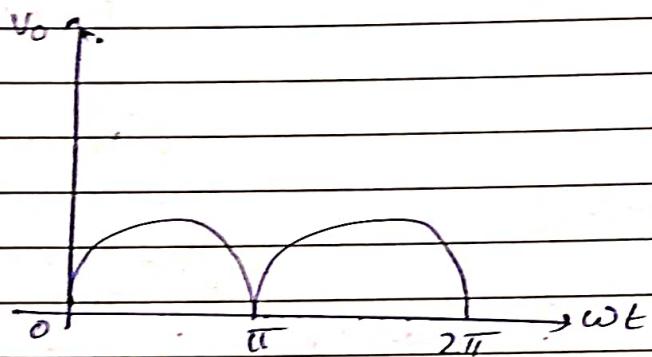
for -ve half cycle

D₁ → OFF D₂ → ON

$$+V_i - V_o = 0.$$

$$\boxed{V_o = V_i}$$

Current in same sense.



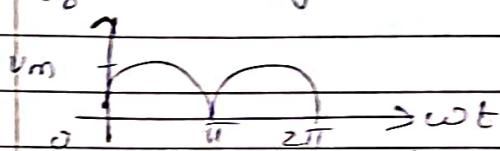
Full Wave Rectification

Avg. Load current is Avg. Load ~~average~~ Voltage.

As we studied earlier the output volt & curr are same for both center tap & bridge full wave

So, the results for avg I & V will be same for both

Avg (dc) voltage:



$$V_o = V_m \sin \omega t \quad 0 < \omega t < \pi$$

$$V_{av} = V_{dc} = \frac{1}{\pi} \int_0^{\pi} V_m \sin \omega t d(\omega t)$$

$$\Rightarrow V_m \left[\frac{-\cos \pi}{\pi} - (-\cos 0) \right]$$

$$V_{av} = V_{dc} = \frac{2V_m}{\pi}$$

Avg load currents

$$I_{av} = \frac{V_{av}}{R} \Rightarrow \frac{2V_m}{\pi R}$$

In H.W.R

$$I_{av} = \frac{2Im}{\pi}$$

$$V_{av} = \frac{V_m}{4}$$

$$V_{fullwave} = 2 V_{halfwave}$$

$$I_{av} = \frac{Im}{\pi}$$

RMS LOAD Current.

$$I = \text{load current}$$

$$I = I_m \sin \omega t \quad 0 \leq \omega t < \pi$$

$$I_{\text{rms}} = \sqrt{\frac{1}{\pi} \int_0^{\pi} I^2 d(\omega t)}^{\frac{1}{2}}$$

$$= \sqrt{\frac{1}{\pi} \int_0^{\pi} I_m^2 \sin^2 \omega t d(\omega t)}^{\frac{1}{2}}$$

$$= \sqrt{\frac{I_m^2}{\pi} \int_0^{\pi} \frac{1 - \cos(2\omega t)}{2} d(\omega t)}^{\frac{1}{2}}$$

$$\Rightarrow \frac{I_m^2}{2\pi} \left[(\pi - 0) - 0 \right]^{\frac{1}{2}}$$

$$\Rightarrow \sqrt{\frac{I_m^2}{2}}.$$

$$\boxed{I_{\text{rms}} = \frac{I_m}{\sqrt{2}}}$$

$$V_{\text{rms}} = I_{\text{rms}} \times R.$$

$$= \frac{I_m}{\sqrt{2}} \times R.$$

$$\boxed{V_{\text{rms}} = \frac{V_m}{\sqrt{2}}}$$

form factor :

$$F.F = \frac{V_{rms}}{V_{av}} \text{ or } \frac{I_{rms}}{I_{av}}$$

$$V_{rms} = \frac{Vm}{\sqrt{2}}$$

$$V_{av} = \frac{2Vm}{\pi}$$

$$\boxed{F.F = \frac{\pi}{2\sqrt{2}} = 1.11}$$

Ripple Factor:

ideally $\gamma=0 \Rightarrow ac=0$.

$$\gamma = \sqrt{F.F^2 - 1}$$

$$\gamma_r = \sqrt{(1.11)^2 - 1} \times 100$$

$$\boxed{\gamma_r = 48.1\%}$$

→ ac-component

now in H.W.R it was 12%

hence we have reduced A-C component.

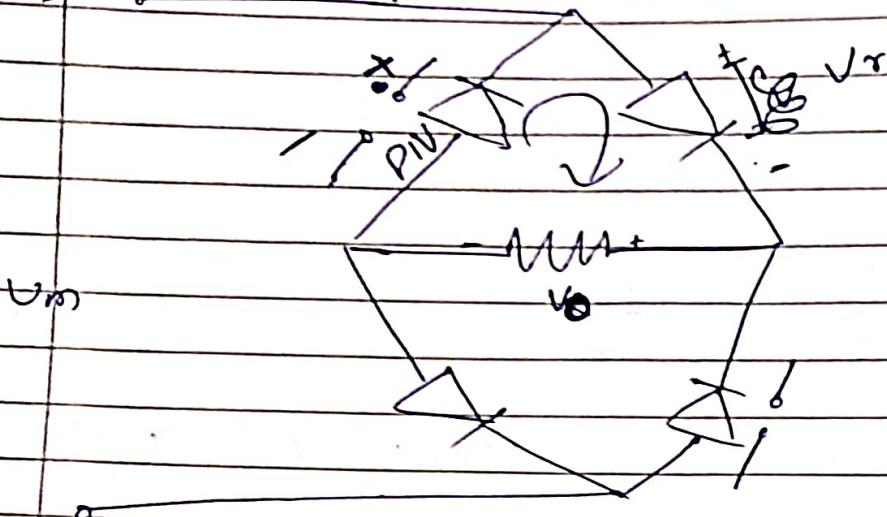
Efficiency

$$\eta = \frac{P_{dc} \times 100}{P_{rms}} = \frac{I^2 d c \times R}{I^2 \omega m \times R} \times 100$$

$$\rightarrow \left(\frac{2Vm}{\pi} \right)^2 \times 100 = 81.13\% \rightarrow P.W.R$$

PIV

(+) Bridge



$$+V_m - V_0 = 0$$

$$V_0 = V_m$$

$$-V_0 + PIV = 0$$

$$PIV = V_m$$

$$PIV \geq V_m$$

for Real Diode

$$-V_0 + PIV - V_r = 0$$

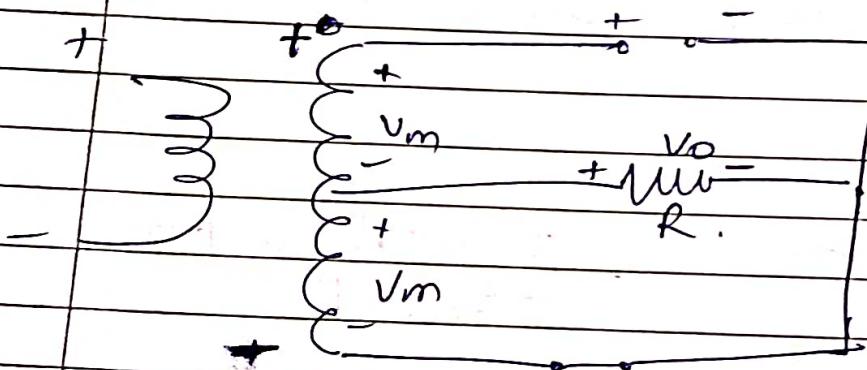
$$PIV \geq V_0 + V_r$$

$$PIV \geq (V_m - 2V_r) + V_r$$

$$PIV \geq V_m - V_r$$

②

Center tap



$$+V_m - V_0 = 0$$

$$V_0 = V_m$$

$$+V_m - PIV + V_0 = 0$$

$$PIV = 2V_m$$

$$PIV \geq 2V_m$$

for real

$$PIV = V_m + V_r$$

$$PIV = V_m + V_m - V_r$$

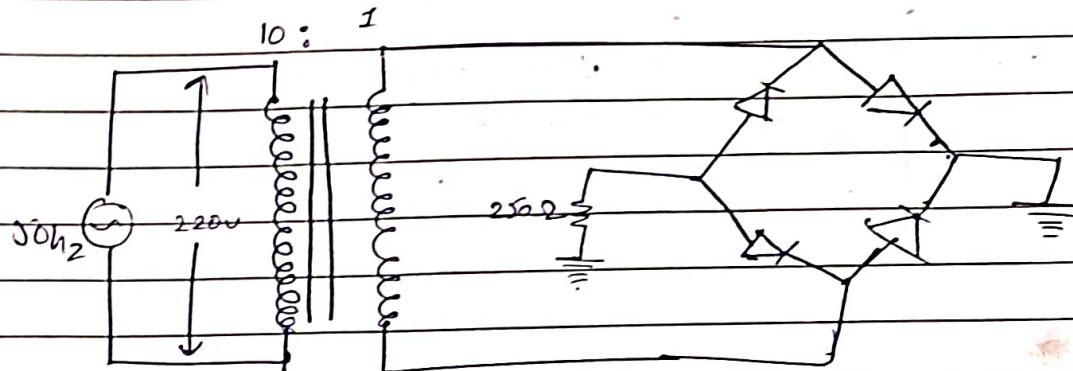
$$PIV = 2V_m - V_r$$

Hence we rarely use Center tap F.W.R

— / —

Q

- a) DC output voltage (v_{out}) Rectification efficiency (η_r)
 c) Peak inverse Voltage (PIV) d) Output frequency (f_o)



$$f_{\text{in}} = 50 \text{ Hz}$$

$$\frac{N_p}{N_s} = \frac{10}{1} = \frac{V_p}{V_s} \quad V_s = \frac{V_p}{10} \Rightarrow \boxed{V_s = \frac{220}{10} = 22 \text{ V}} = V_L = V_{\text{avg}}$$

$$(a) \quad V_{\text{avg}} = \frac{2 V_m}{\pi} \Rightarrow 2 \times \frac{V_m}{\pi}$$

$$(A_3, \quad V_{\text{rms}} = \frac{V_m}{\sqrt{2}})$$

$$V_m = \sqrt{2} V_{\text{rms}}$$

$$= \sqrt{2} \times V_{\text{in}}$$

$$\Rightarrow \frac{2\sqrt{2}}{\pi} \times V_{\text{in}}$$

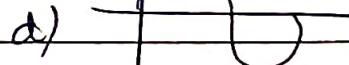
$$\Rightarrow \frac{2\sqrt{2}}{\pi} \times V_{\text{in}} = \frac{2\sqrt{2}}{\pi} \times 22 = 19.81 \text{ V}$$

$$(b) \quad \approx \frac{P_{\text{out}}}{P_{\text{in}}} = \frac{I_{\text{dc}}^2}{I_{\text{rms}}^2}$$

$$\Rightarrow \left(\frac{\frac{2 I_{\text{in}}}{\pi}}{I_{\text{in}}} \right)^2 \Rightarrow \left(\frac{2\sqrt{2}}{\pi} \right)^2 = \frac{8}{\pi^2}$$

$$(c) \quad PIV \geq V_m$$

$$\Rightarrow 81.11 \text{ VOUTS.}$$



$$f_i = \frac{1}{T} \quad T = \frac{1}{f}$$

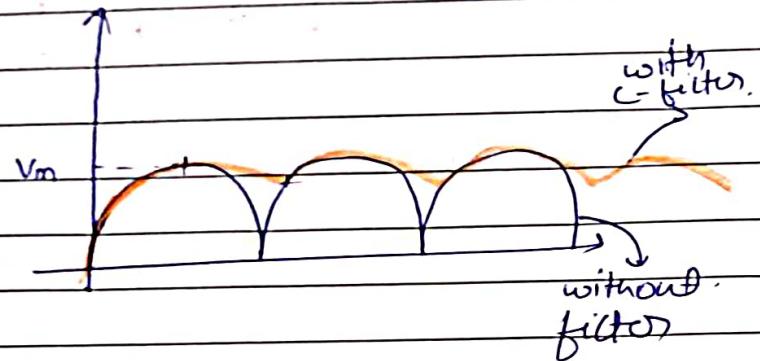
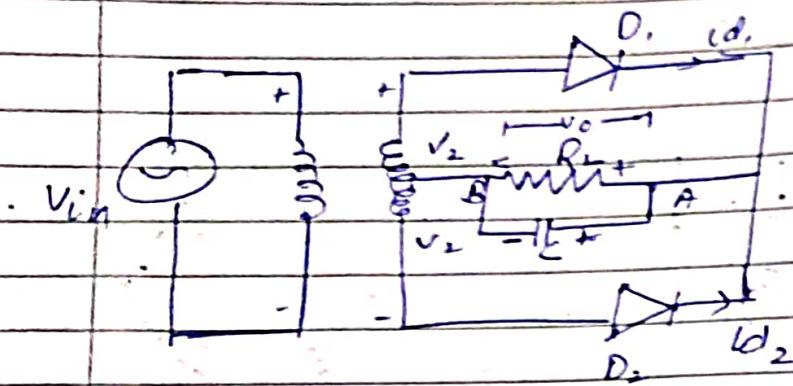
$$T' = \frac{1}{2} T \quad T = \frac{1}{2} T'$$

$$f_o = 2 f_i \quad f_o = 60$$

$$f_o = 2 f_i \eta$$

11

PULL WAVE RECTIFIER WITH CAPACITOR FILTER



charge $V_E > V_C$.

discharge $V_I < V_C$

Now we have to again pass the filter through voltage regulator, to get dc-voltage.

